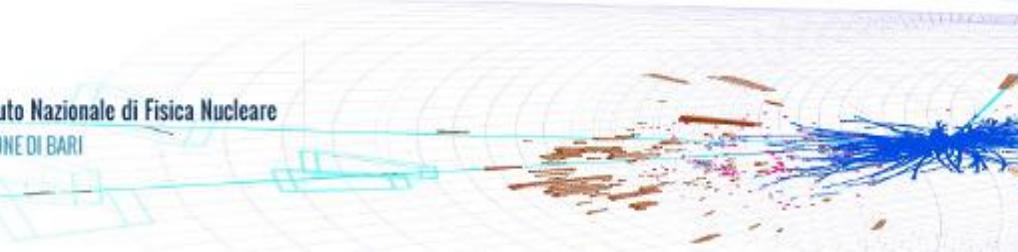


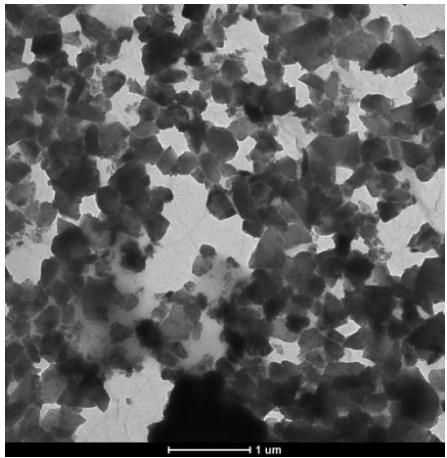


Istituto Nazionale di Fisica Nucleare  
SEZIONE DI BARI

DIPARTIMENTO INTERATENEO DI FISICA  
“M. MERLIN”



# *DIAMOND FILM* *(RD in Bari)*



**RD51 Mini-Week**  
**10 -13 Feb. 2020 at CERN**

*Antonio Valentini et al.*  
*INFN – Sezione di Bari*



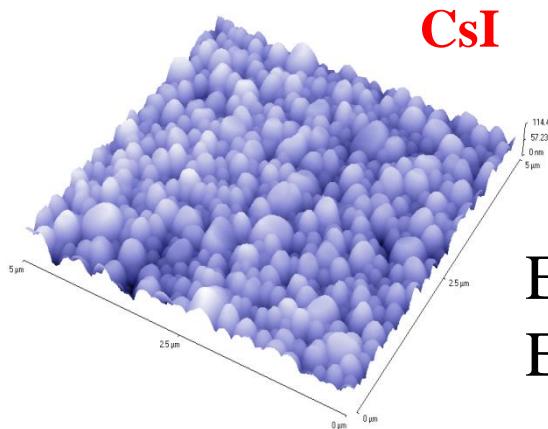
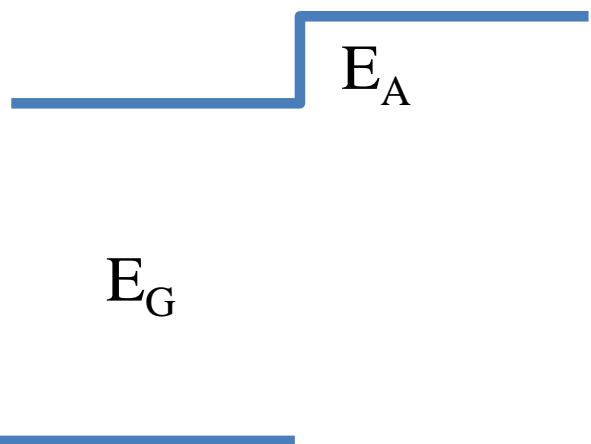
# PCs

## QUANTUM EFFICIENCY (QE)

- Increase with  $\frac{E_G}{E_A}$  ratio

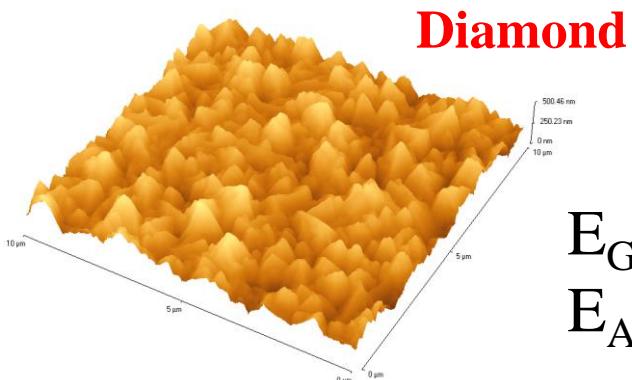
- $E_G > E_A$ 
  - Scattering electrons-phonons;

- $E_G < E_A$ 
  - Scattering electrons-phonons;
  - Secondary electron generation.



$$E_G = 6.2 \text{ eV}$$

$$E_A = 0.1 \text{ eV}$$

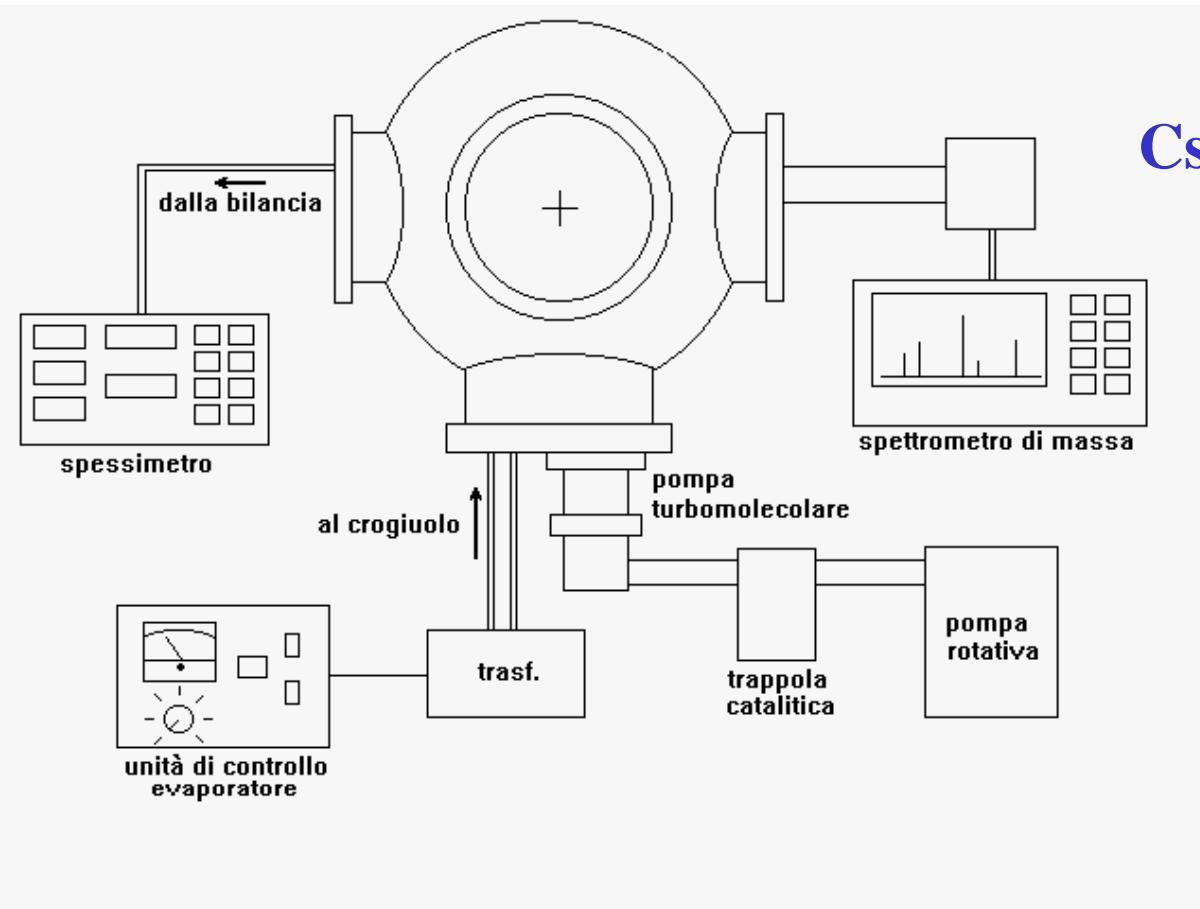


$$E_G = 5.5 \text{ eV}$$

$$E_A < 1 \text{ eV}$$

1995

## *Start research on CsI PCs*

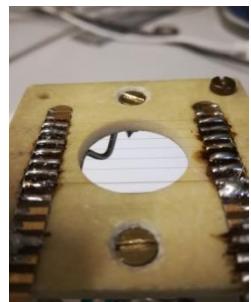


CsI Thermal Evaporator

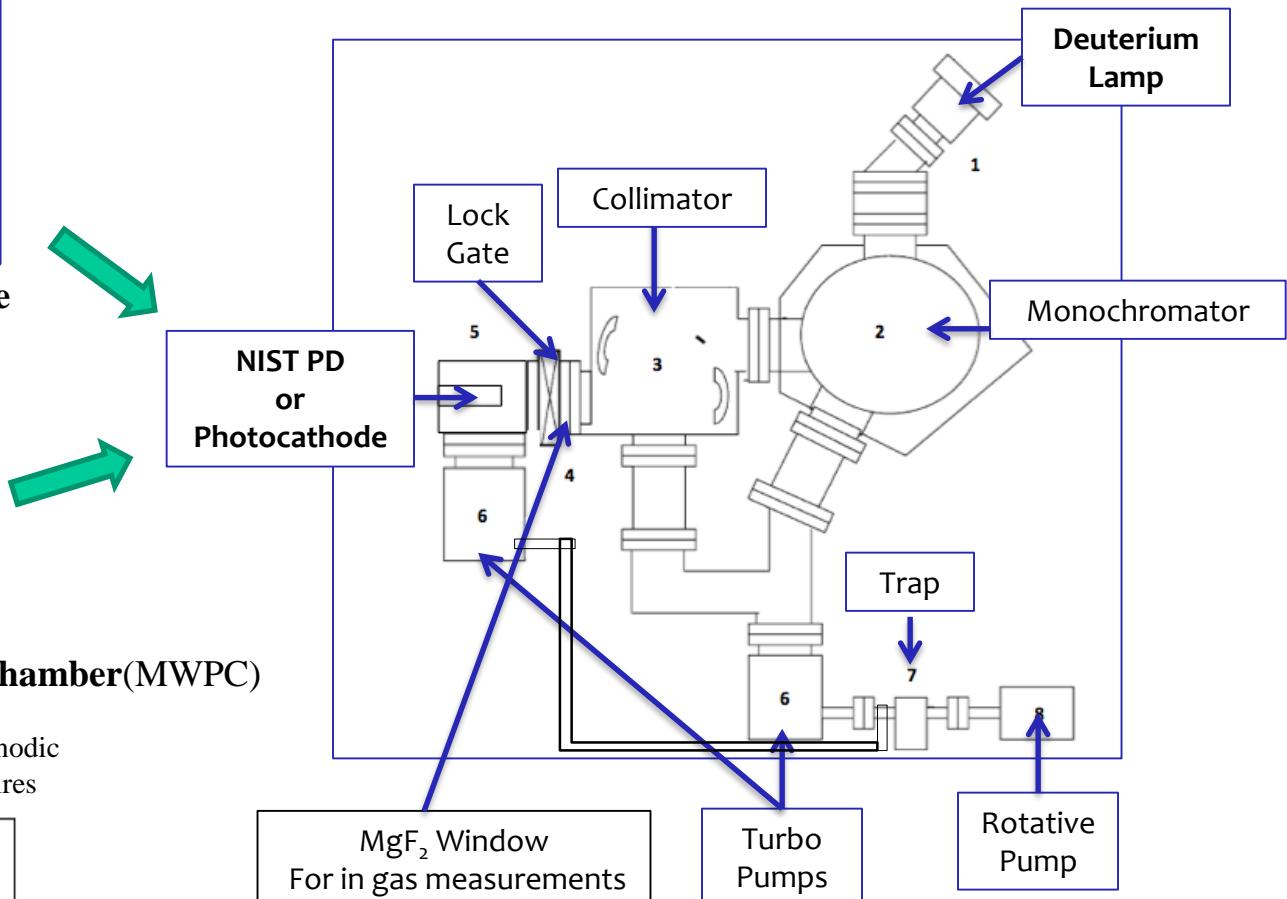
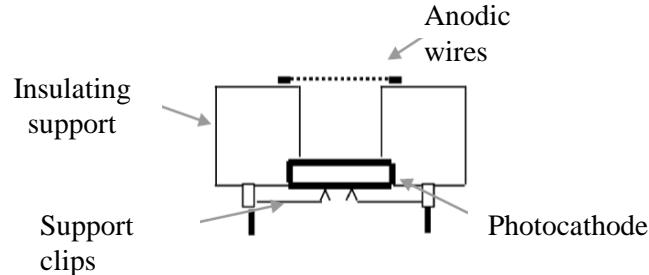
# QE MEASUREMENT SETUP



**NIST Photodiode**

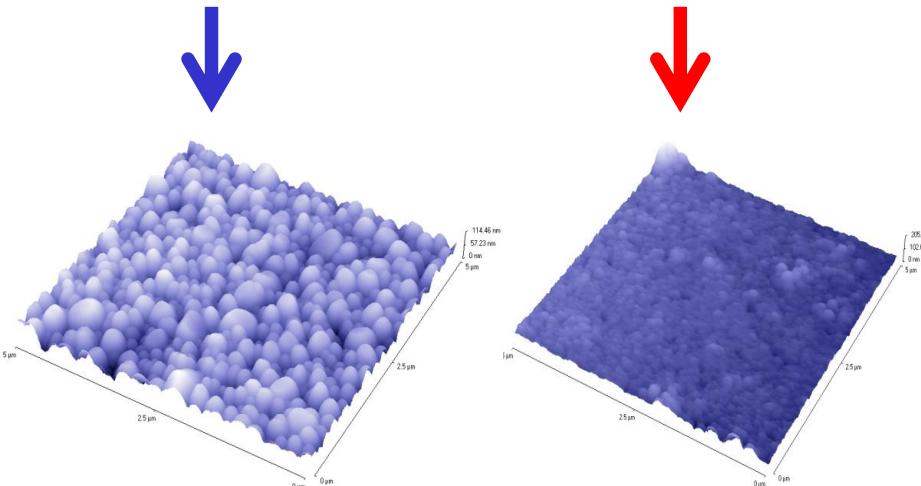
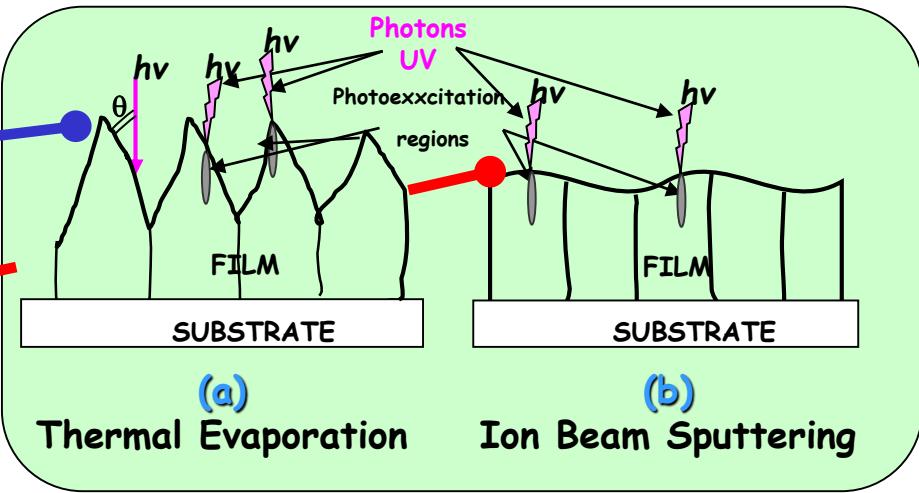
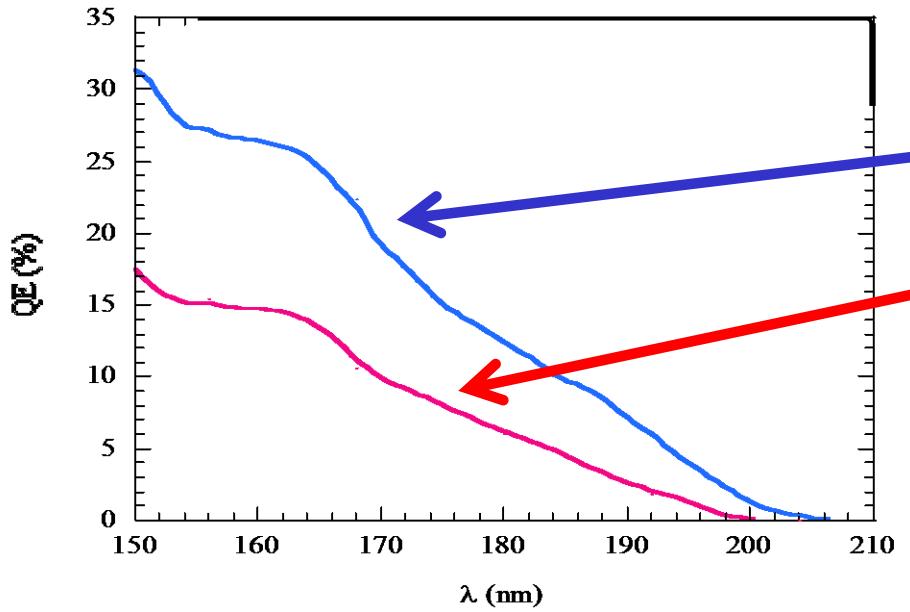


**Multiwire Proportional Chamber(MWPC)**





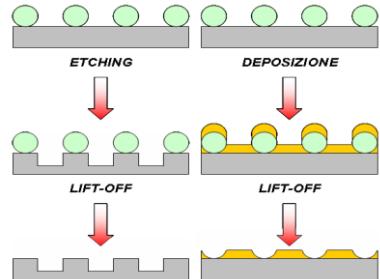
## QE – *Surface Roughness Effects*



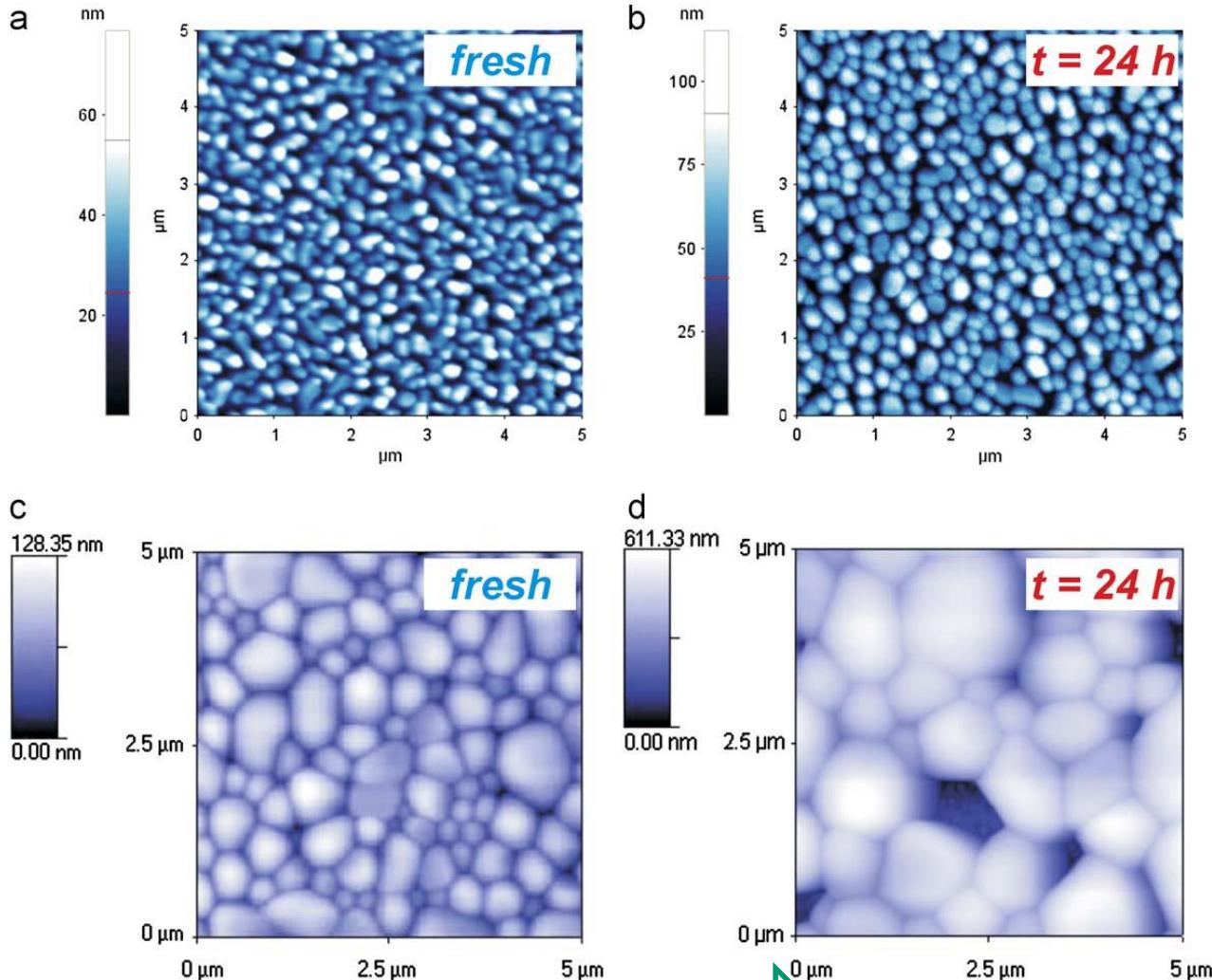


## Aging Processes - Effects and Grain Sizes

**Nanostructured CsI**  
Colloidal lithography  
with  
**Polystyrene balls**



LPLT -Low Power Low Temperature  
Plasma Etching



## Microstructured CsI

M.A. Nitti et al.  
Nuclear Instr. and Met. in Phys. Res. A  
610 (2009) 234–237

CsI

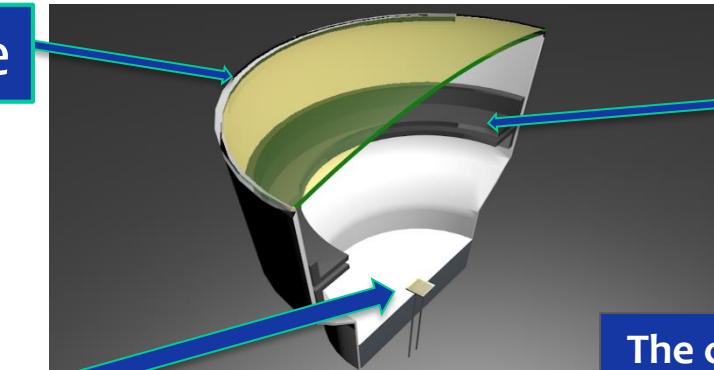
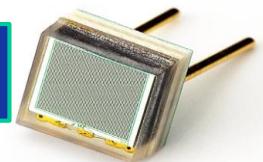
*Head-On*

An innovative design for a modern hybrid photodetector based on the combination of a Silicon PhotoMultiplier (SiPM) with a hemispherical vacuum glass PMT standard envelope

Photocathode

Focusing Ring

e-SiPM



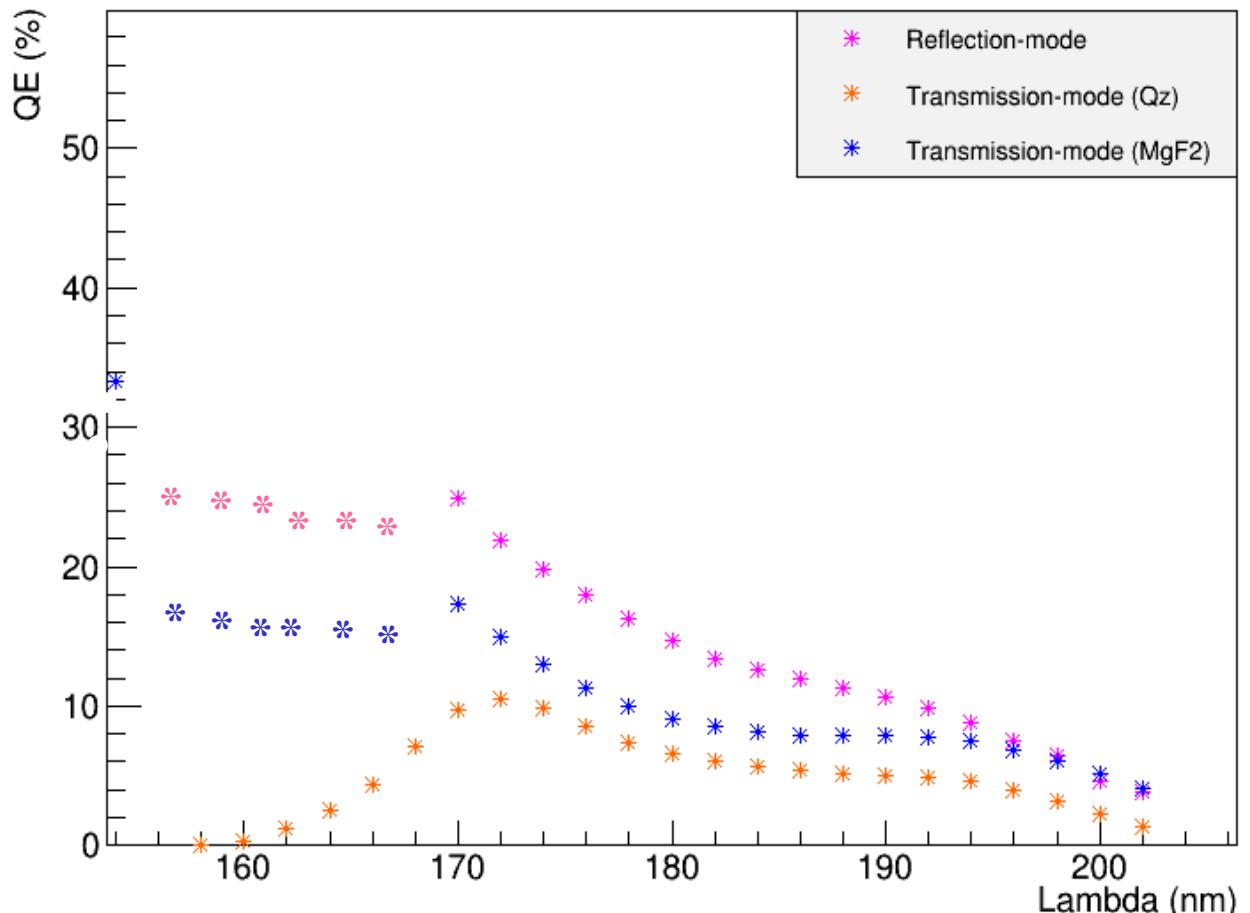
The classical dynode chain of a PMT is replaced with a special windowless SiPM, acting as an electron multiplying detector (e-SiPM).

## Photocathode realization

Optical Window

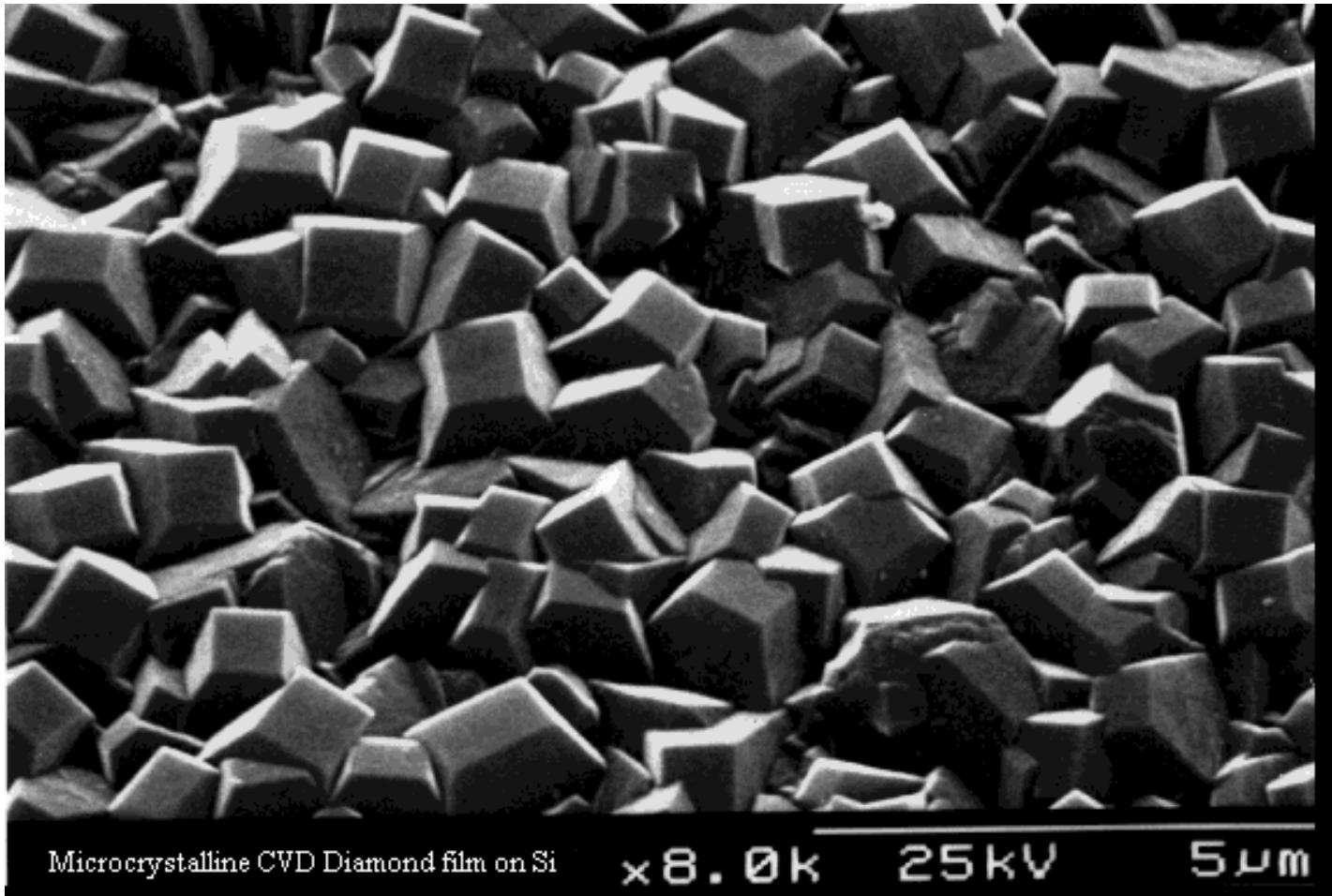
Conductiv e Layer

Photo-cathode



(C 2.5 nm + Ni 0.5 nm) + CsI (20 nm)

# Diamond Applications in *VUV Photocathodes*



# Diamond Applications in *VUV Photocathodes*

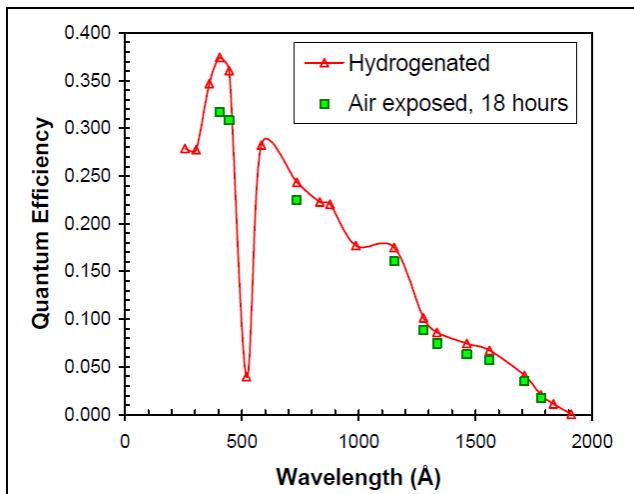
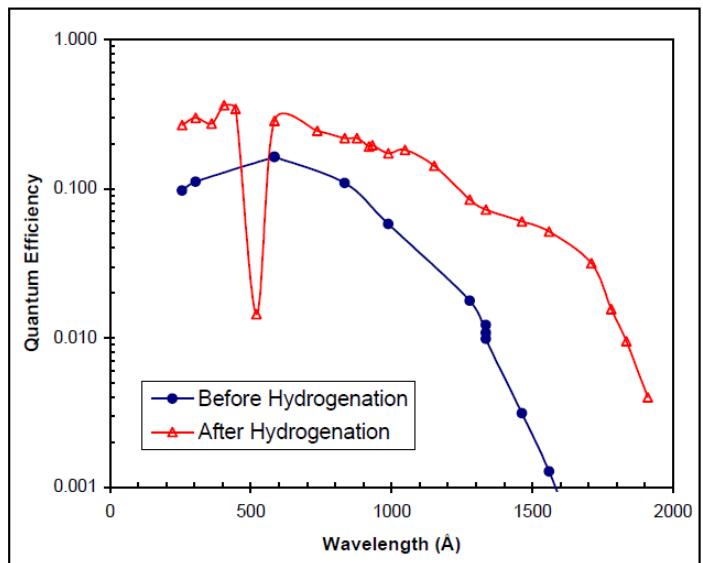


Proceedings SPIE, vol. 4139, San Diego, California (2000)

## Polycrystalline diamond films as prospective UV photocathodes

A.S. Tremsin\* and O.H.W. Siegmund

Experimental Astrophysics Group  
Space Sciences Laboratory  
UC Berkeley  
Berkeley, CA 94720



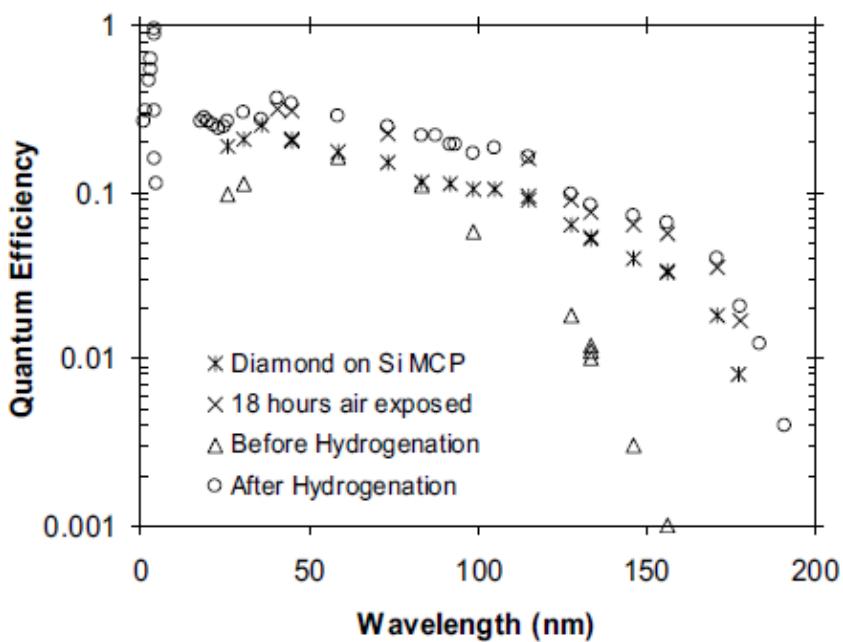
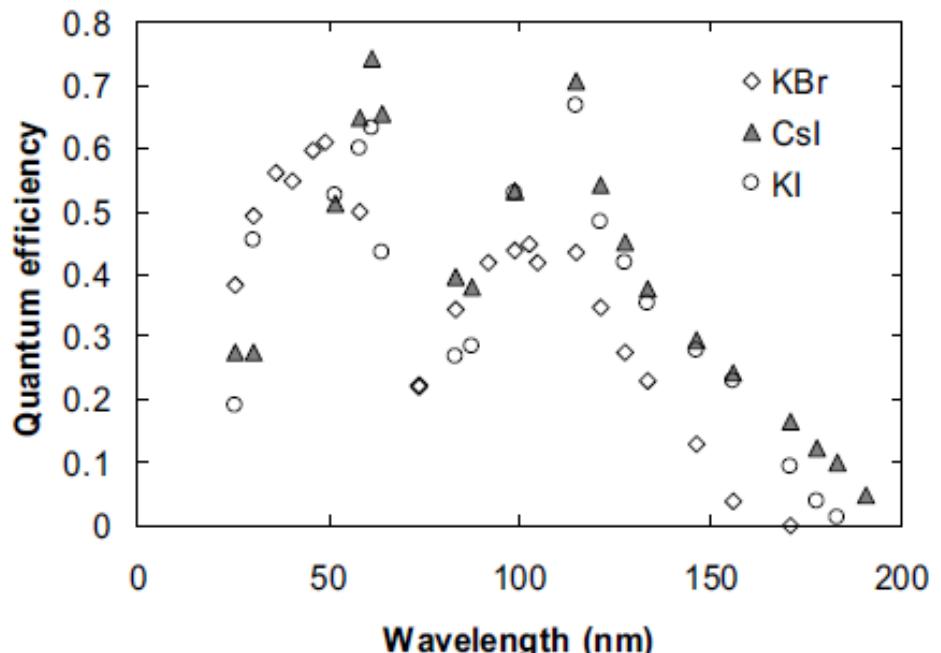
# Diamond Applications in

## *VUV Photocathodes*

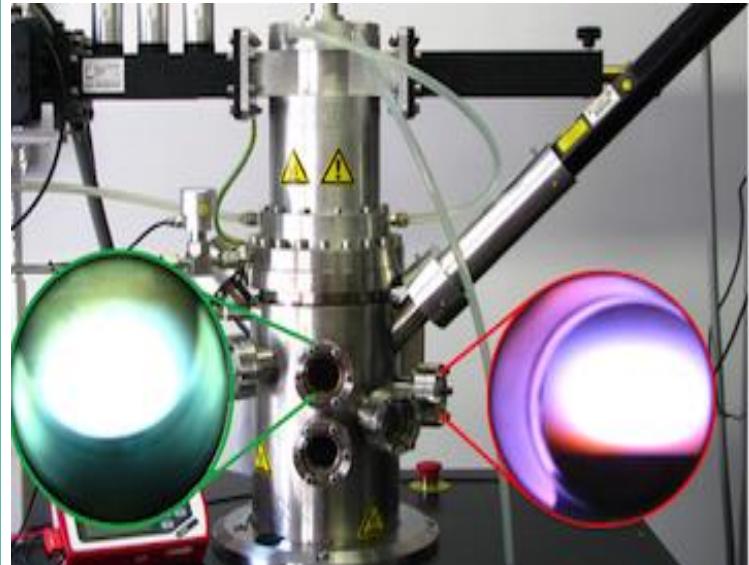
The quantum efficiency and stability of UV and soft X-ray photocathodes

Anton S. Tremsin\*, Oswald H. W. Siegmund

Proceedings of SPIE - The International Society for Optical Engineering · August 2005



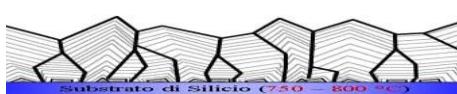
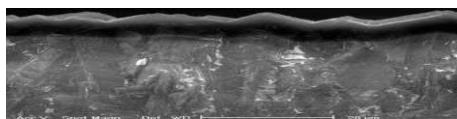
## Chemical Vapor Deposition

*Diamond film growth in Bari*

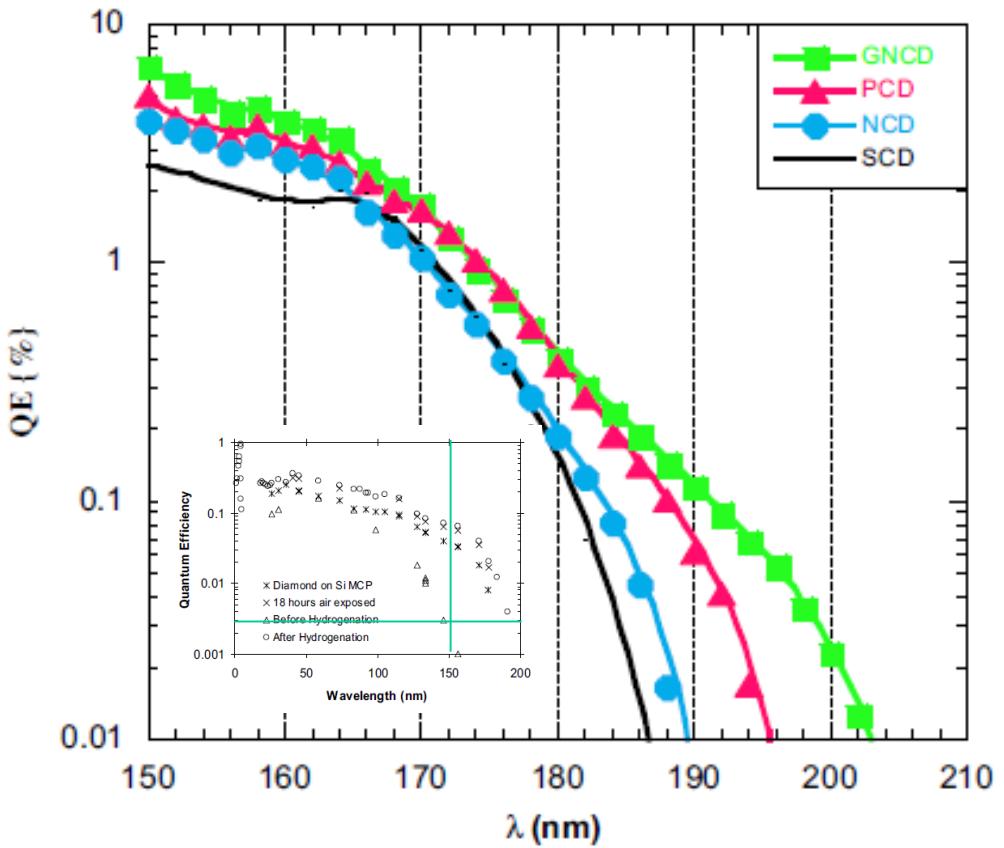
G. Cicala  
CNR-ISTP Sezione di Bari

1. UHV reactor coupled to a Microwave generator (2.45 GHz)
2. Highly diluted CH<sub>4</sub> in H<sub>2</sub> (CH<sub>4</sub>< 4%)
3. High deposition temperatures (**750-900 ° C**)
4. High power inputs of the Microwaves (0.45-2.5 kW)
5. High pressures (10-200 mbar)

*Polycrystalline  
film*



## *QE - Grain Properties Effects*

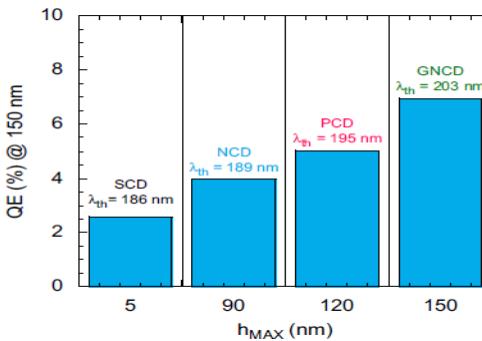
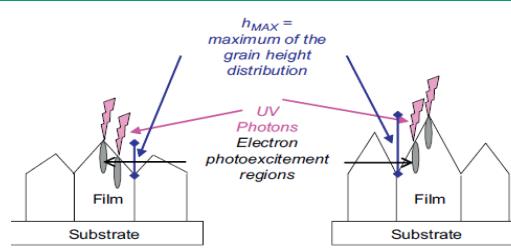


**GNCD**-Graphite NanoCrystalline

**PCD**-PolyCrystalline Dia

**NCD**-NanoCrystalline Dia

**SCD**-SingleCrystal Dia



$h_{max}$  from AFM

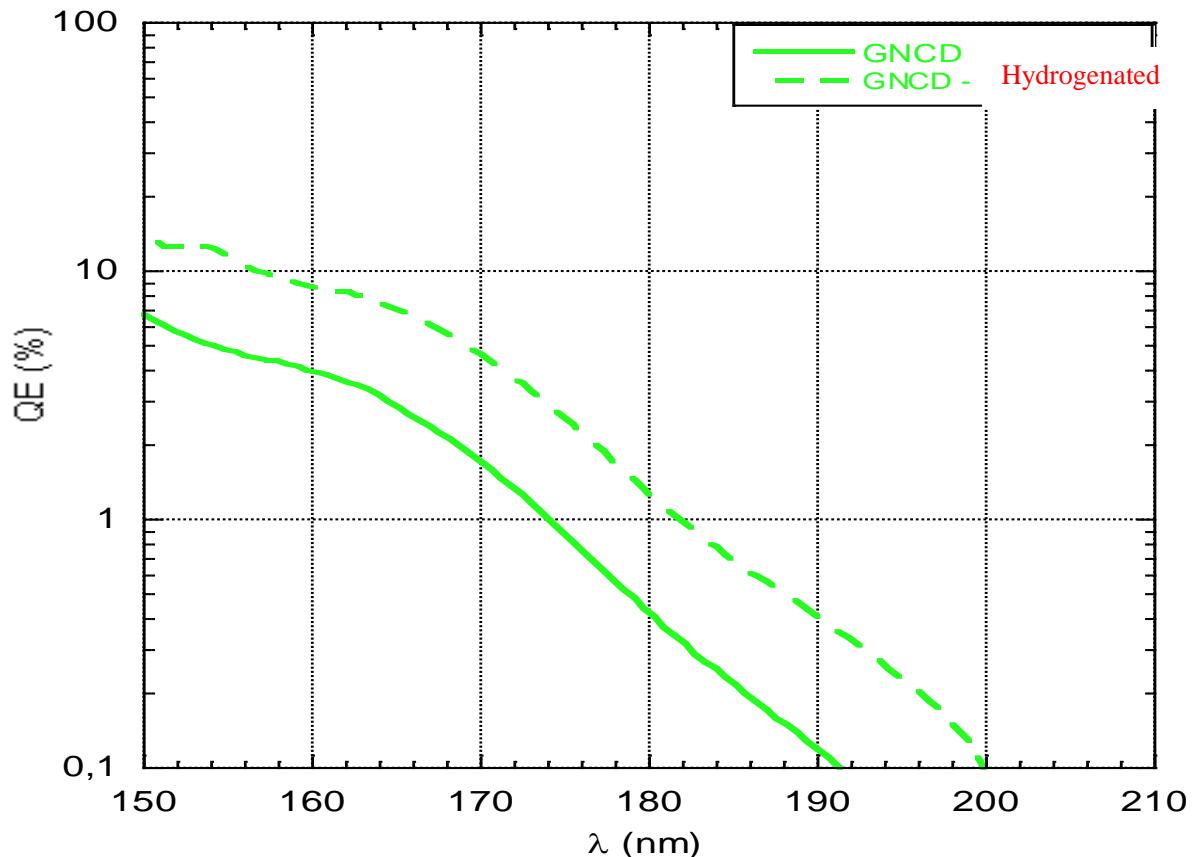
M.A. Nitti, et al.

Nuclear Instr. and Met. in Phys. Res. A  
595 (2008) 131–135



# DIAMOND PHOTOCATHODES (MWPECVD)

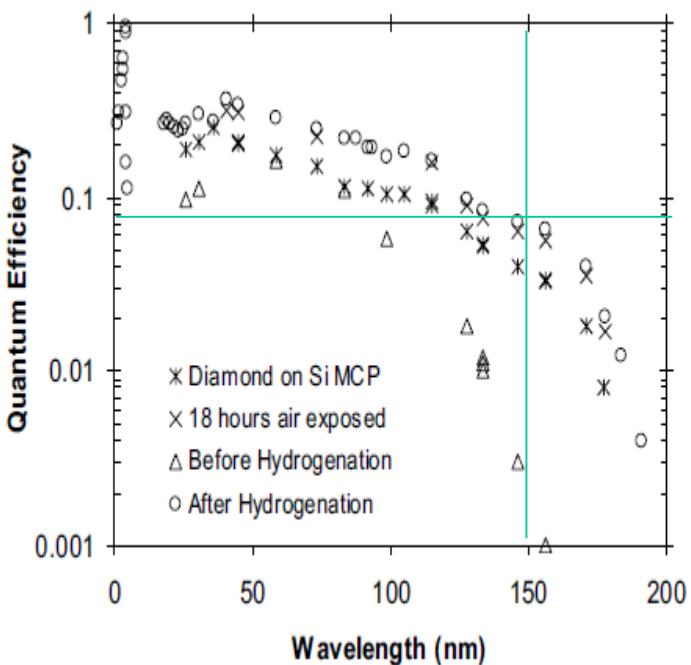
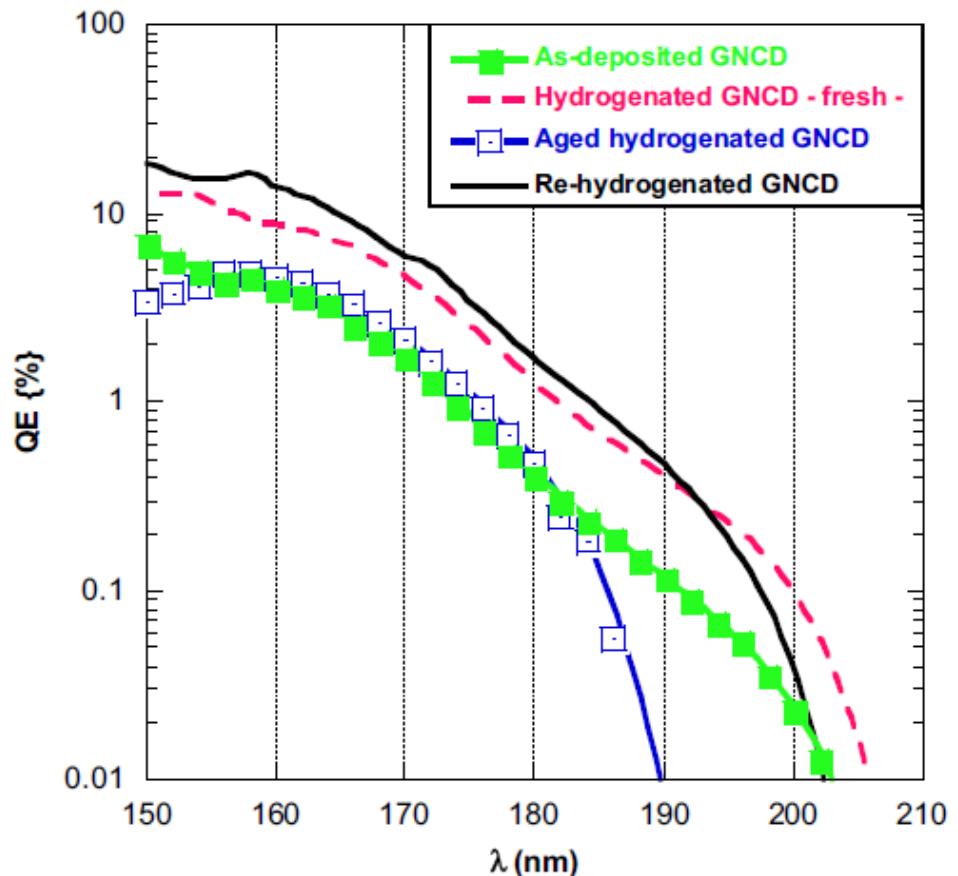
*QE – Hydrogenated Diamond*



M.A. Nitti, et al.

Nuclear Instr. and Met. in Phys. Res. A  
595 (2008) 131–135

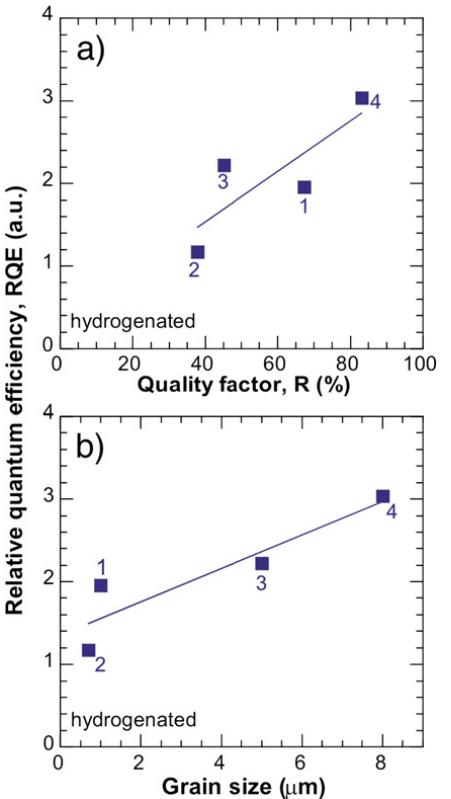
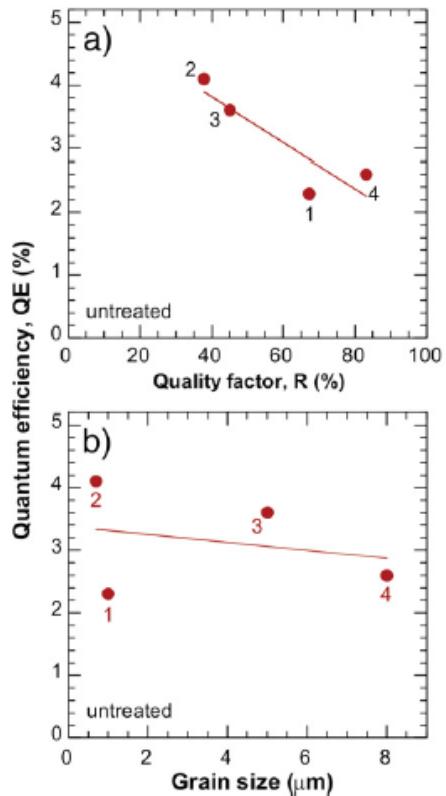
## *QE – Ageing Effects on Hydrogenated Diamond*



M.A. Nitti, et al.

Nuclear Instr. and Met. in Phys. Res. A  
595 (2008) 131–135

## *QE -Hydrogenated Diamond*



**Before hydrogen plasma treatment**

The higher sp<sup>2</sup> content (lower R%) seems to improve the photocathode performance, independent of the grain size.

**After hydrogen Plasma treatment**

Hydrogenation affects only the diamond component of the film

Larger grain size and Lower sp<sup>2</sup>

Higher QE

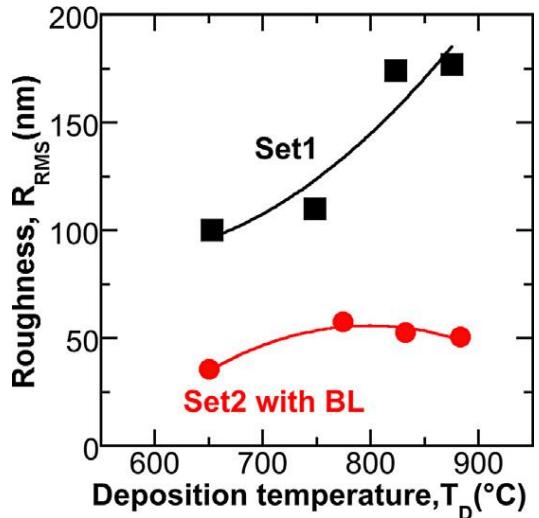
$$RQE = QE_{\text{hyd.}} / QE_{\text{untr.}}$$

# Photo- and Thermionic Emission of MWPECVD

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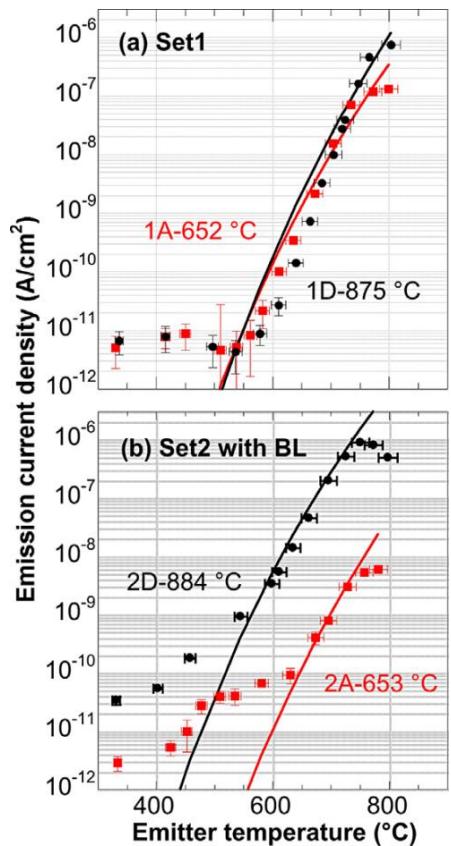
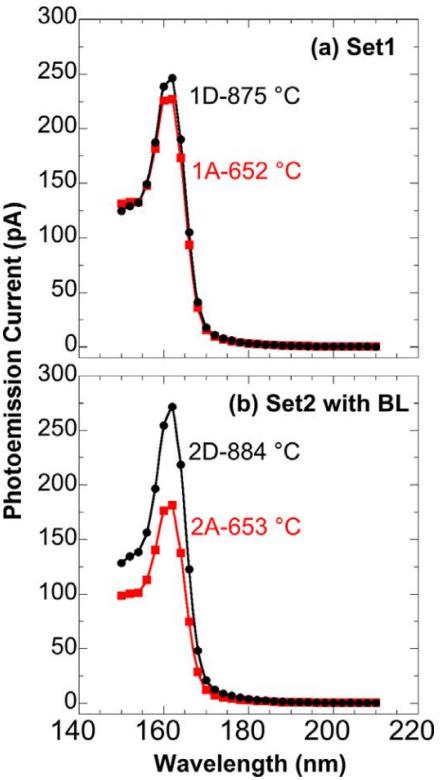


## Nanocrystalline Diamond Films.



The Buffer Layer (BL) of Set2 is microcrystalline diamond

The NCD films with BL grown at the highest deposition temperature have shown the highest photo- and thermionic emission currents.



The solid lines are the Richardson–Dushman curve fits.

# DIAMOND POWDERS

*Nanodiamond ( $\leq 250$  nm)*

(a)



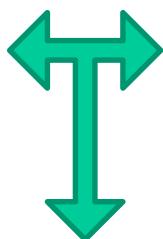
(b)



*Rich-Diamond*



(a')

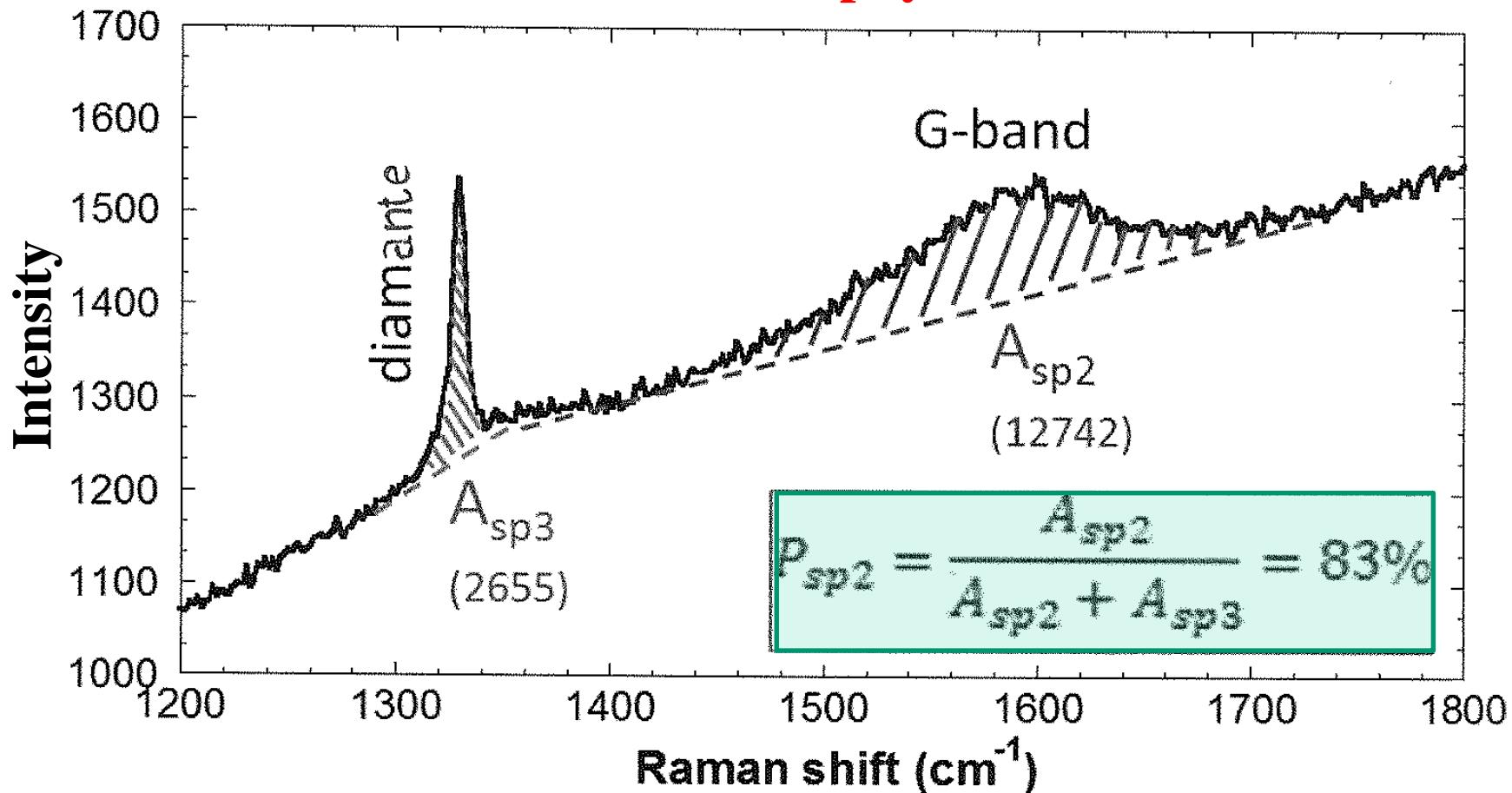


*Rich-Graphite*

(b')



Solutions in  
(DCE)  $\rightarrow$  H<sub>2</sub>O

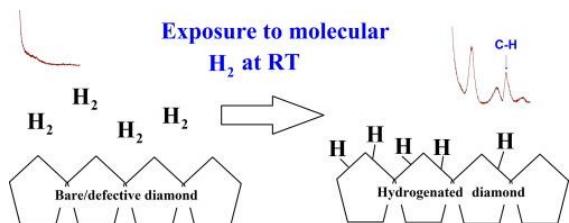
POWDER  
CHEMICAL PROPERTIESRAMAN  
Rich-Graphyte



# MATERIAL TREATMENTS IN

## HYDROGEN PLASMA

**Annealing in Hydrogen** (T around 500°C): is a process that involves the treatment of material in the flow of a molecular hydrogen gas H<sub>2</sub>, which remains so, or affects defective diamond.



**Plasma Hydrogen Treatment** (T in the range 850-1200 °C): the molecule H<sub>2</sub> is ionized by producing ions of the type H+, H<sub>2</sub>+, ecc., and gets excited by forming species of the kind H<sub>2</sub>\*, H\* (Hα, Hβ, Hγ, ecc.) that, decaying in their fundamental state (H\* → H+hv), produce the typical Plasma glow.

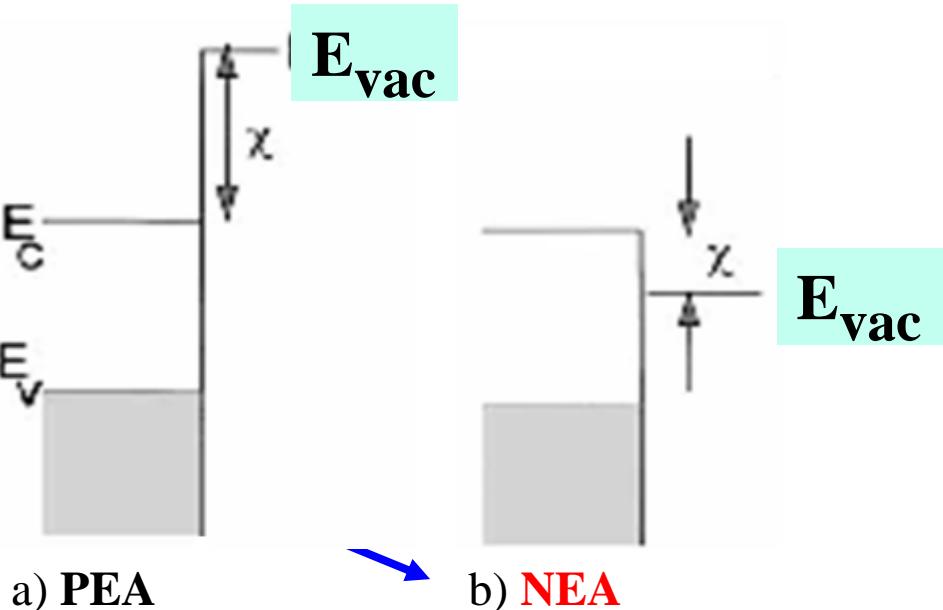
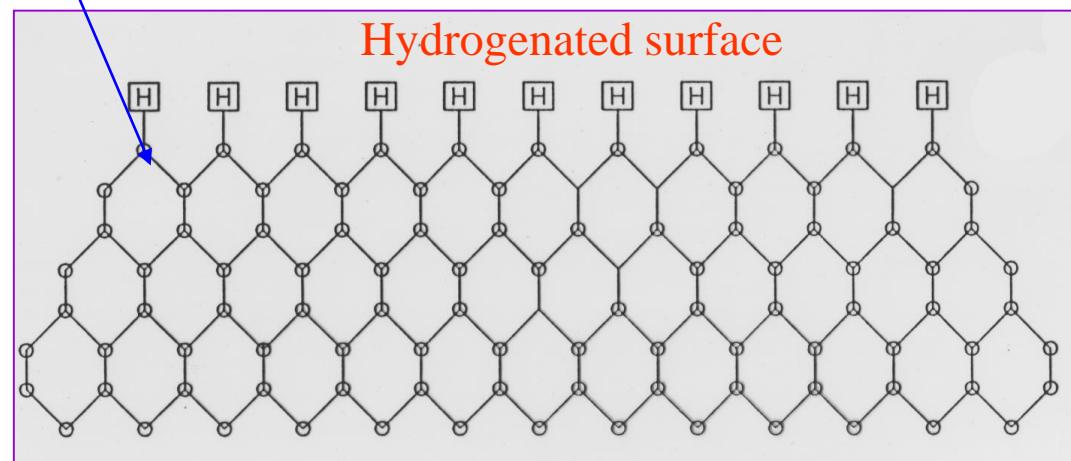
Under such conditions, the production of *active species* is more efficient.

These highly reactive species lead to the formation of  
*C-H bonds*  
with much higher probability  
compared to an H<sub>2</sub> flow annealing process.

# Hydrogen Plasma Effects

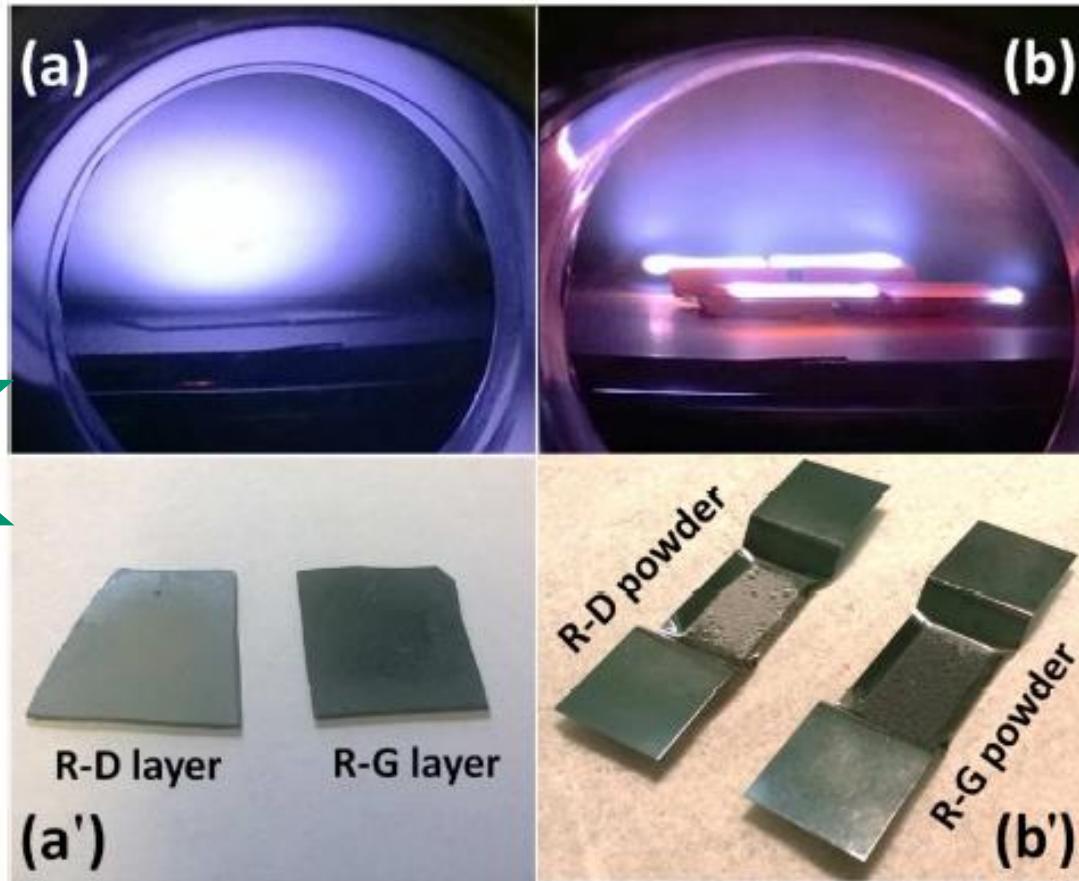
The surface of the diamond treated with hydrogen leads to a **Negative Electronic Affinity (NEA)**

○ C atoms



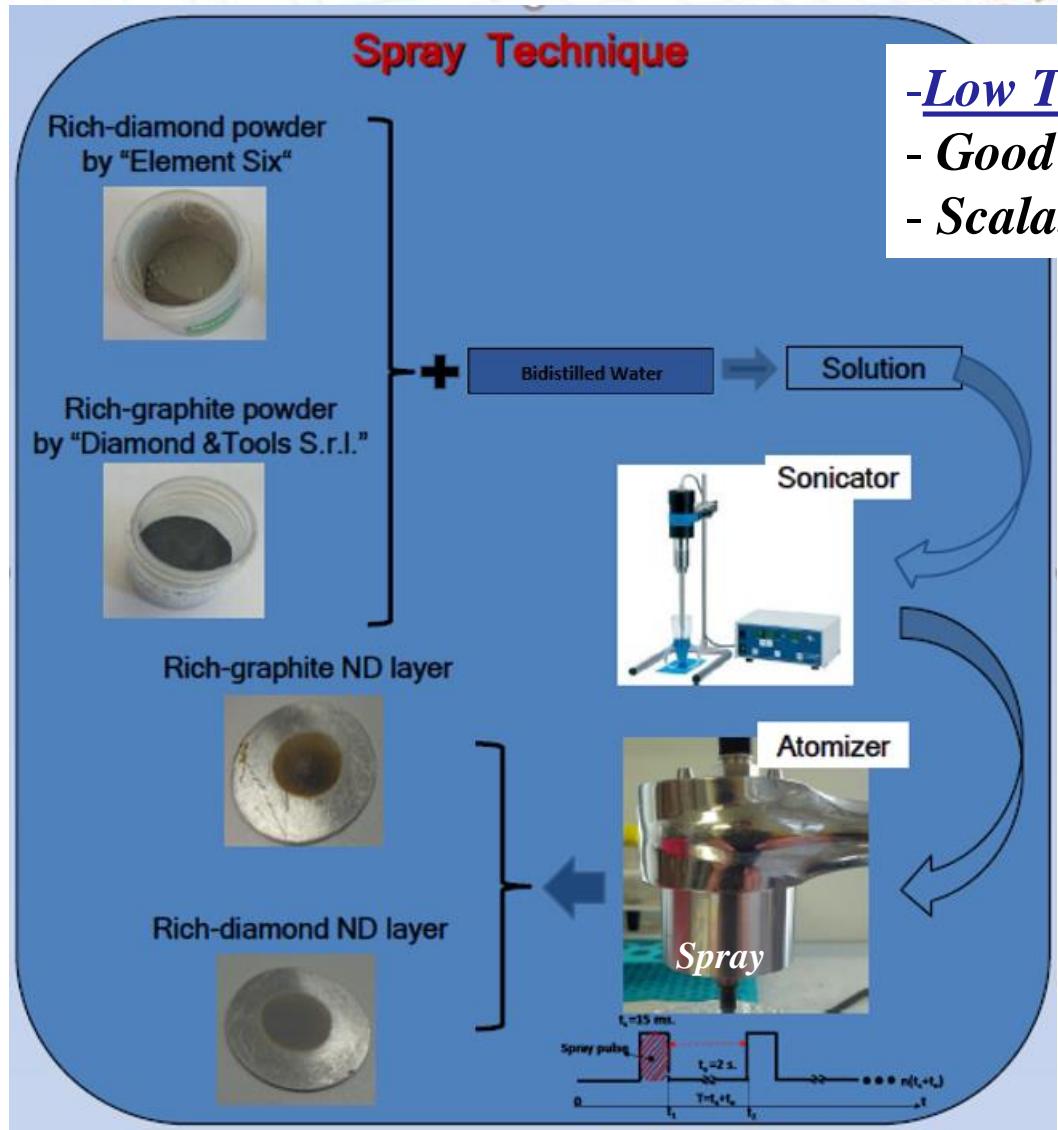
The hydrogenated surface leads to the formation of **C-H polar bonds** that allow the lowering of the Electronic Affinity

# Hydrogen Plasma



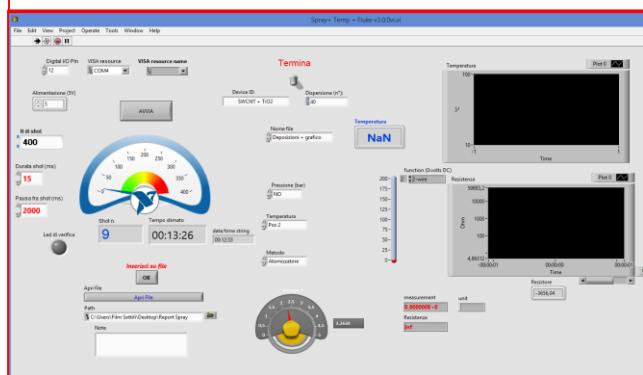


# Diamond Layer Growth



- Low Temperature Deposition ( $\leq 120^\circ\text{C}$ )
- Good reproducibility technique
- Scalable to cover large areas

## Spray Control Interface



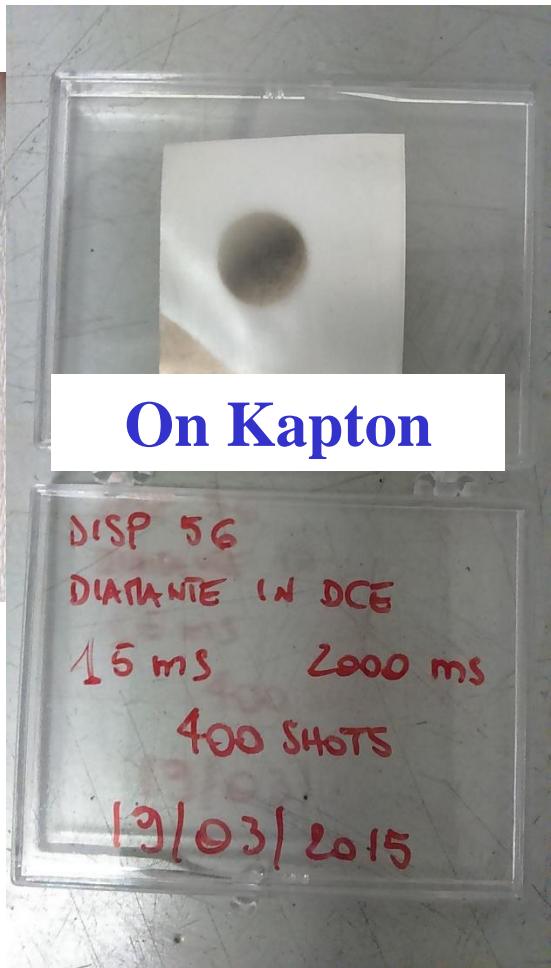


# DIAMOND PHOTOCATHODES

## SPRAY METHOD



**R-D**  
On PCB



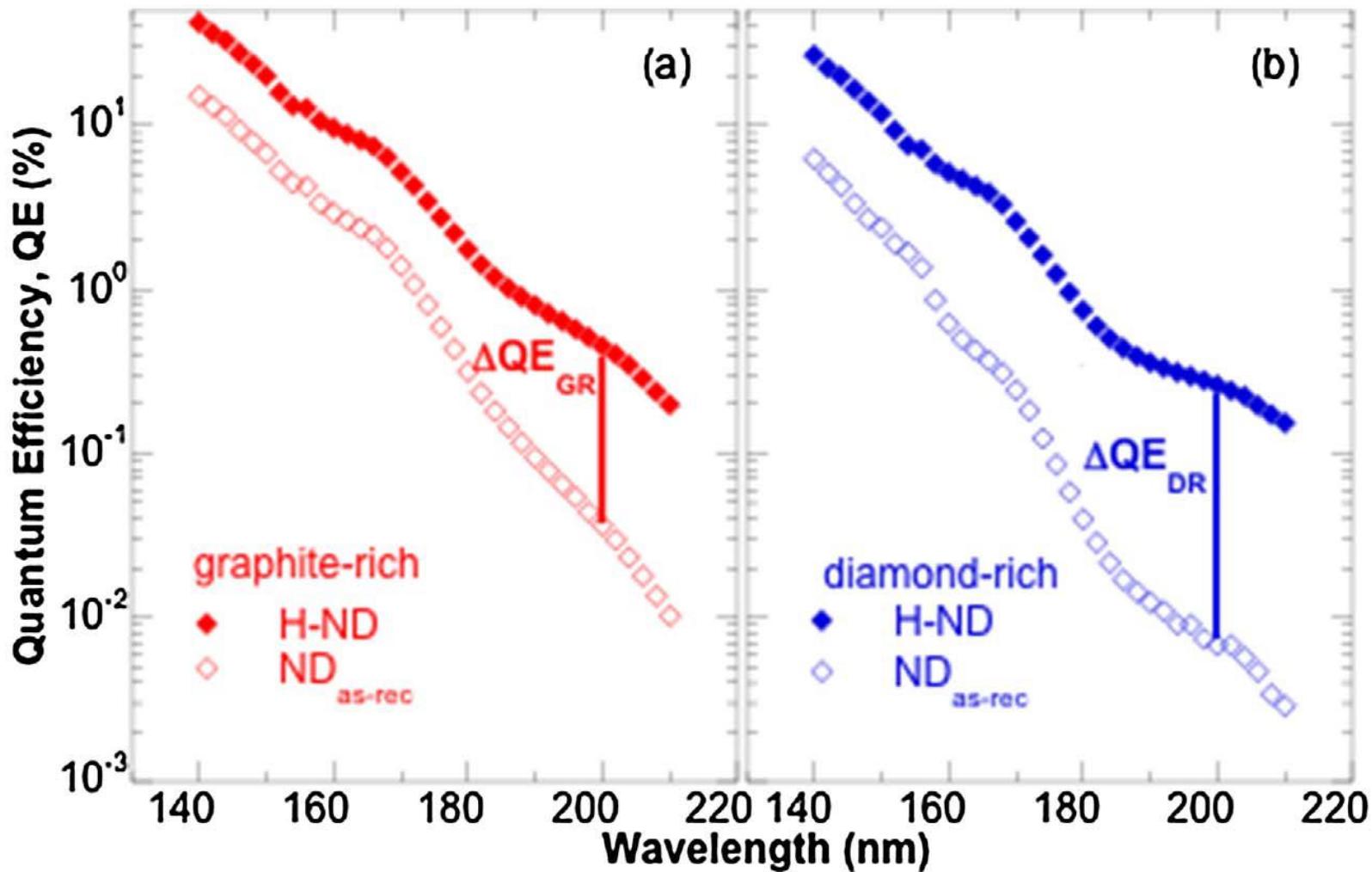
**R-G**  
On PCB

*International Patent Application  
PCT/IB2016/055616*



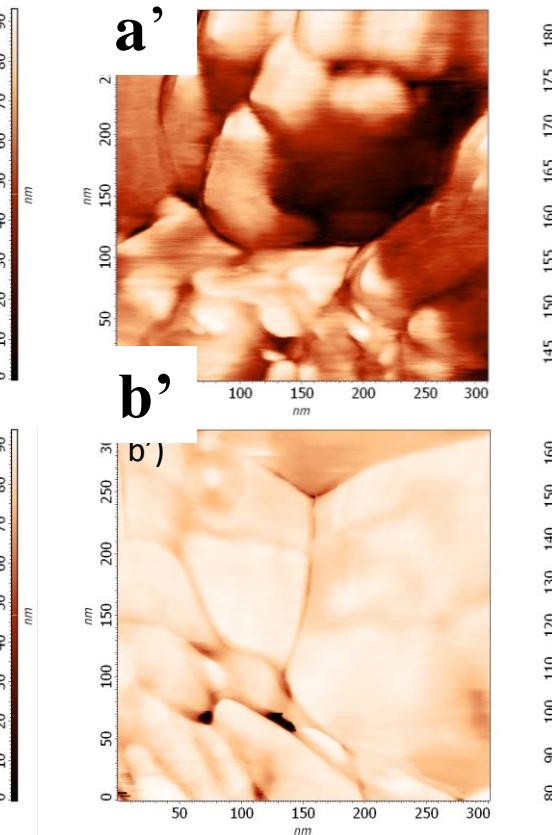
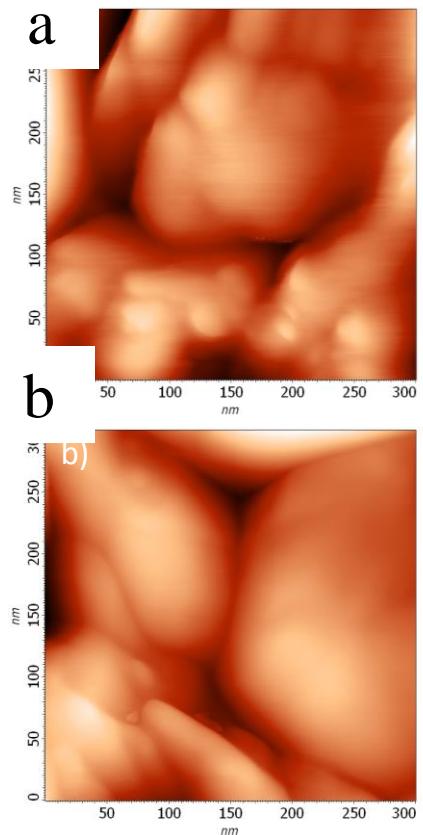
# DIAMOND PHOTOCATHODES

## SPRAY METHOD





# SPRAY DIAMOND FILMS

**AFM****IN PHASE CONTRAST****R-G****R-D**

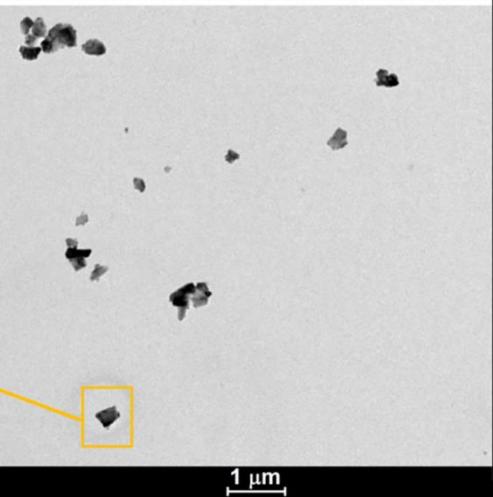
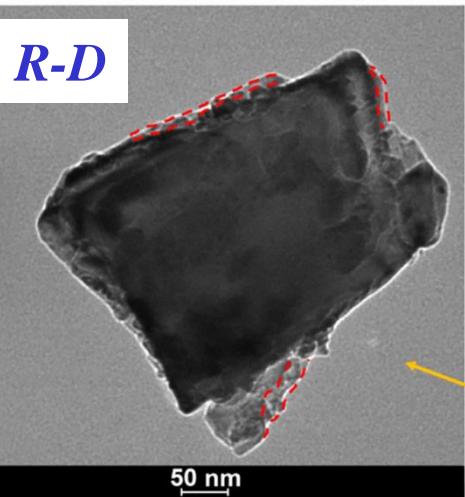
The **dark regions** (**Fig. a'**) represent the contribution of graphite  $sp^2$  on diamond  $sp^3$

The **bright regions** (**Fig. b'**) represent the contribution  $sp^3$  on graphite  $sp^2$

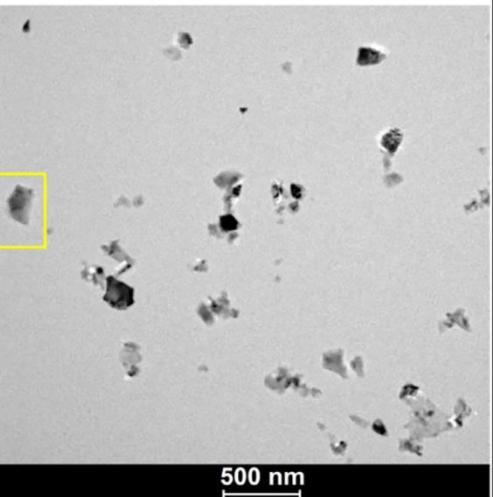
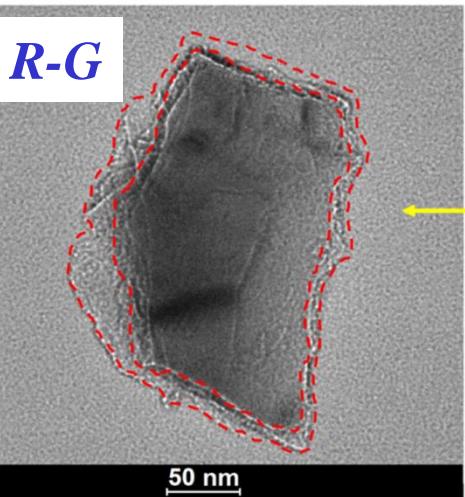


## DIAMOND GRAINS

**R-D**

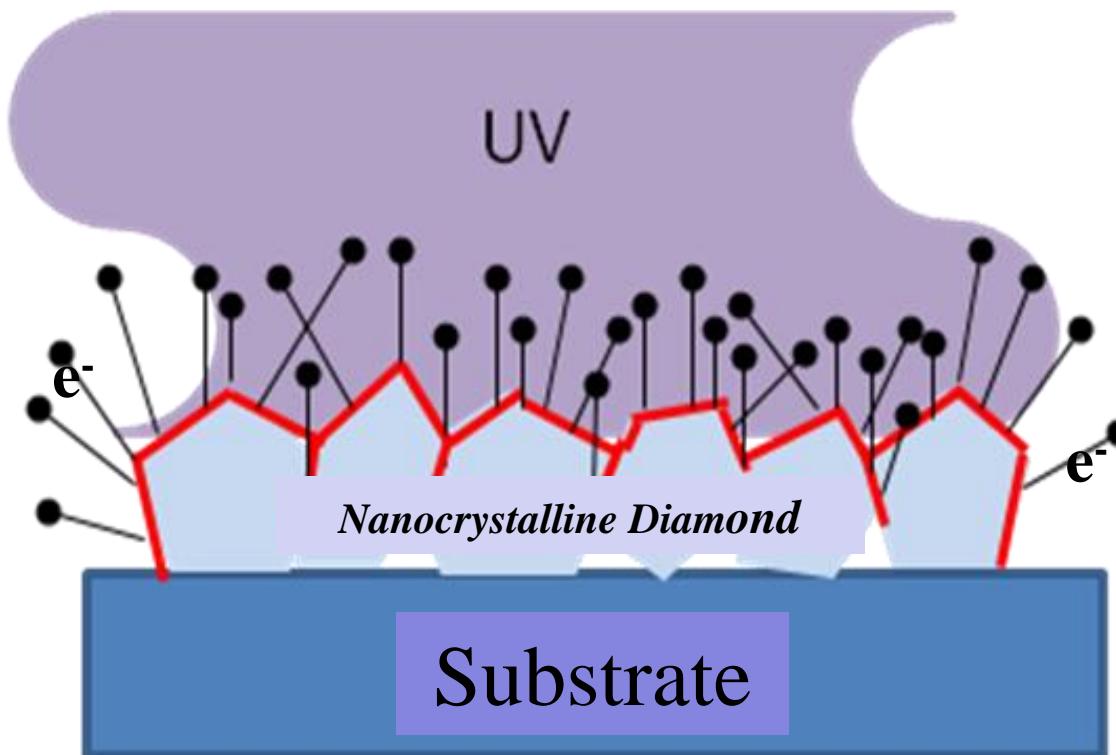


**R-G**



In **hatred** highlighted  
the ***sp*<sup>2</sup>** component  
present  
*at the Grain Boundaries*

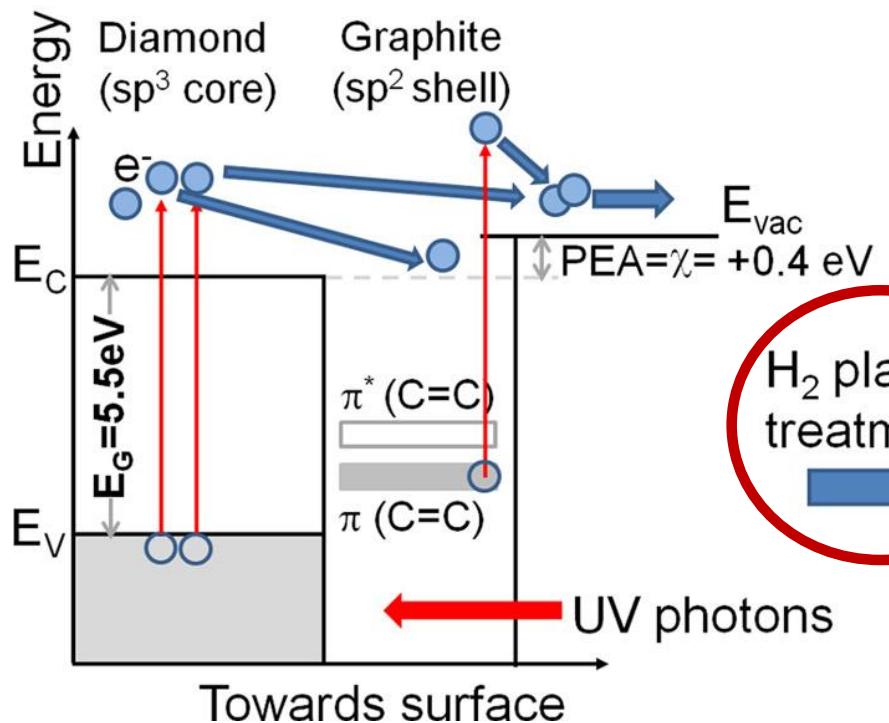
*Emission favored at the grain boundaries*



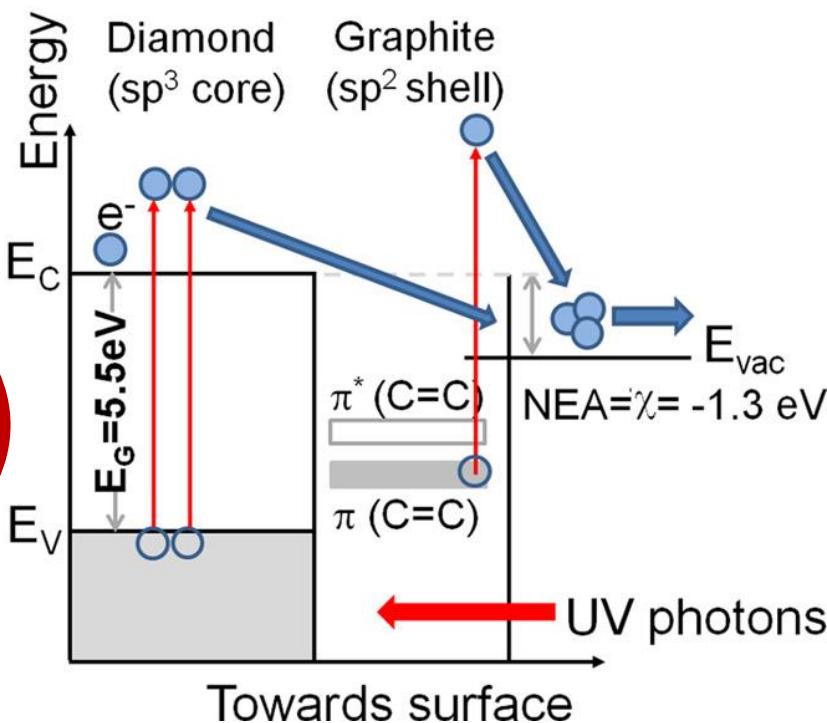
Graphite at the grain boundaries can help the charge neutralization !!



## (a) Untreated ND ( $\text{ND}_{\text{as-rec}}$ )



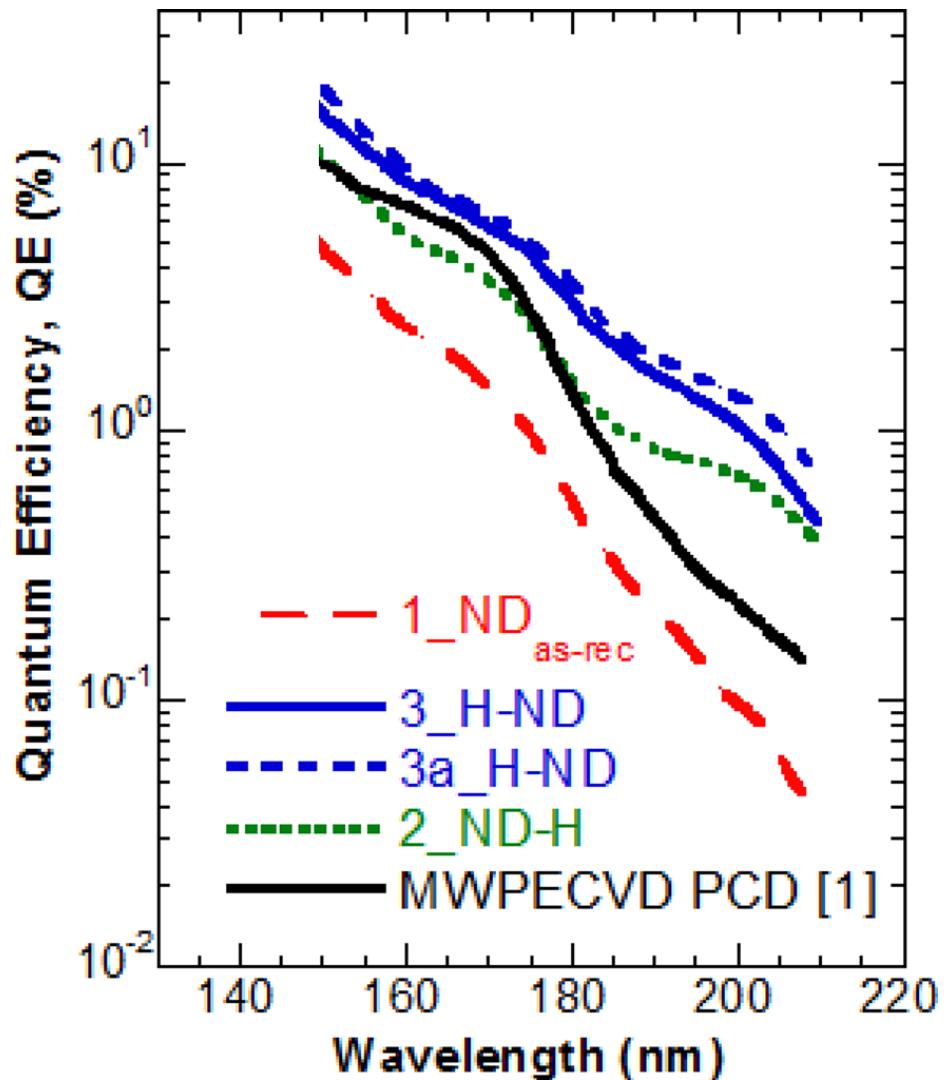
## (b) Hydrogenated ND (H-ND, ND-H)



Schematic representation of the process of photoemission components **sp<sup>3</sup>** e **sp<sup>2</sup>** for **PEA** (a) and for **NEA** (b)

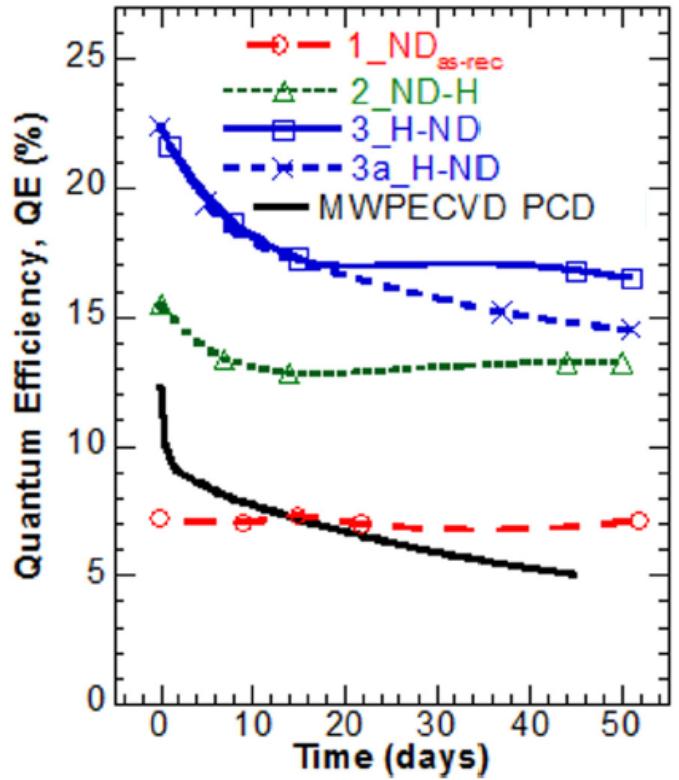


# Quantum Efficiency





## *QE Decay for Hair Exposure*

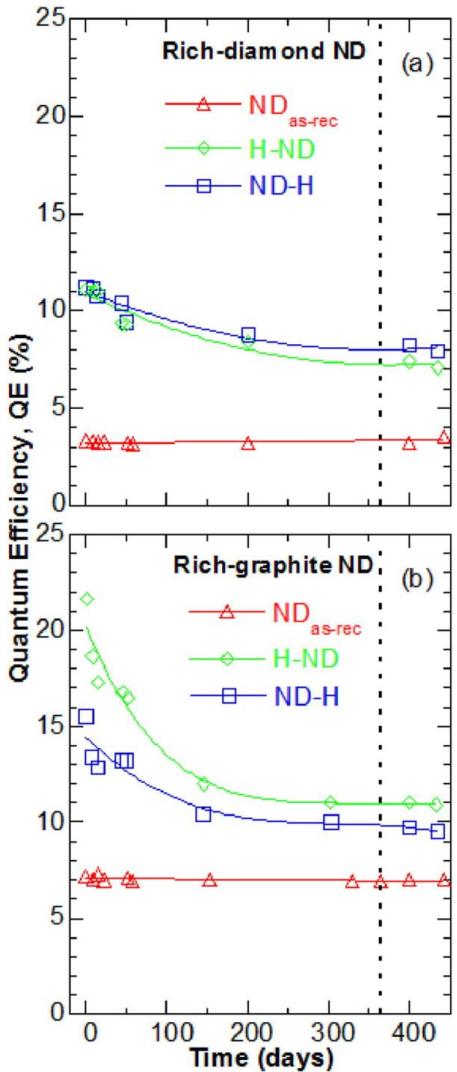


**ND-H**

Hydrogenated film  
After Spray

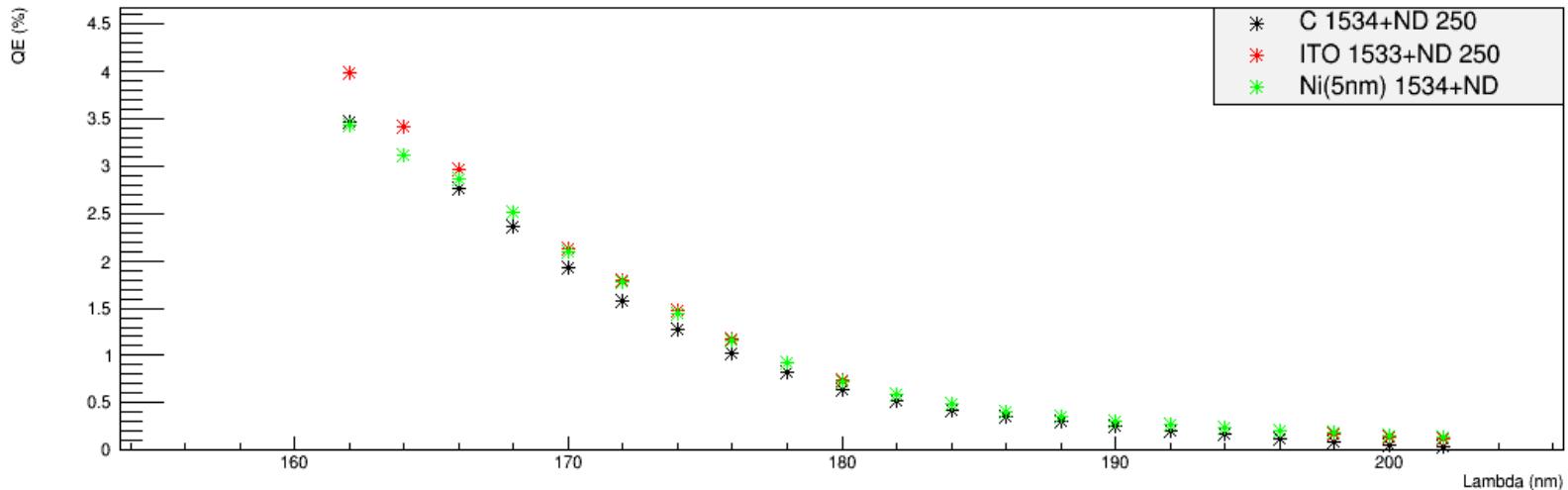
**H-ND**

Hydrogenated powder  
Before Spray

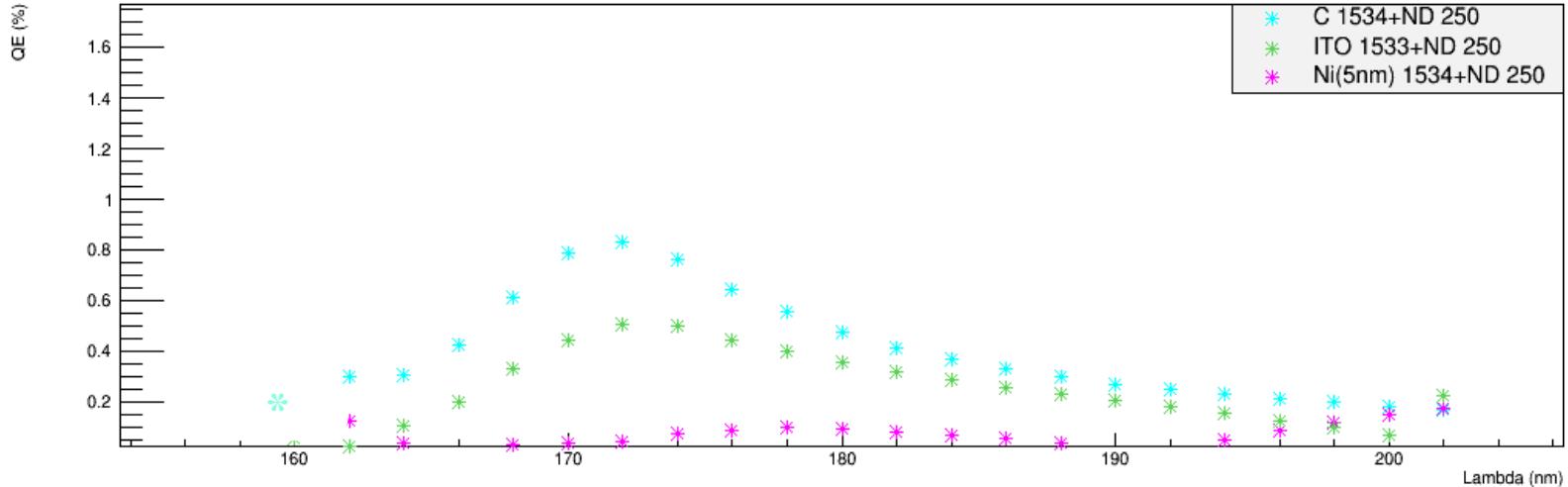


# Head-On Photocathodes

## QE Diamond – *Reflection mode*



## QE Diamond – *Transmission mode mode*

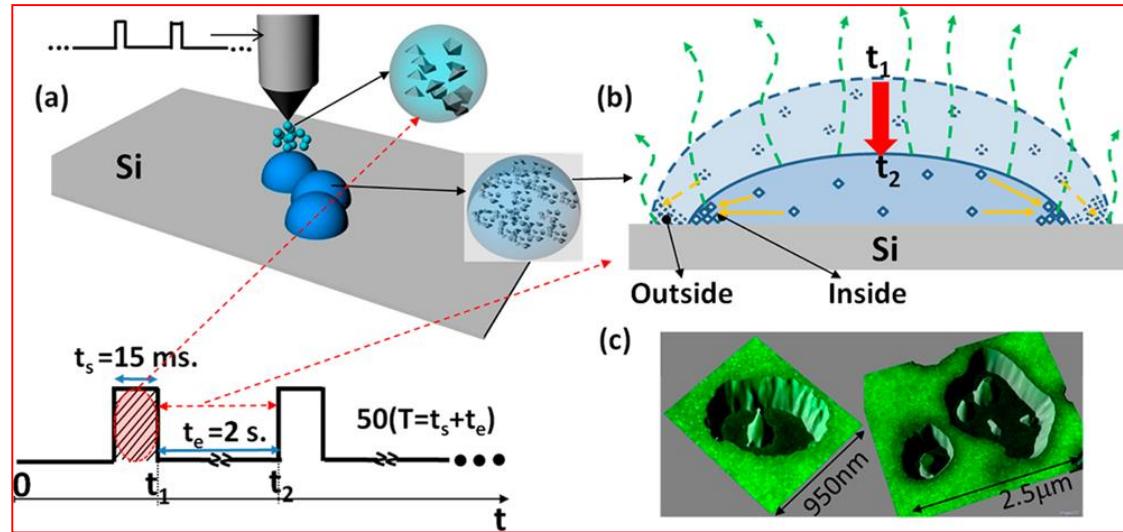




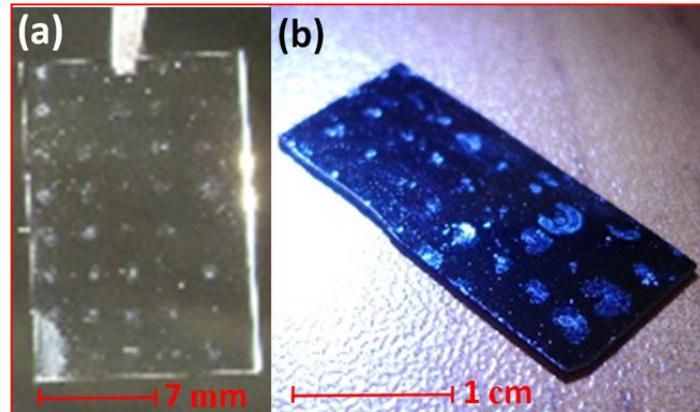
# Nanodiamond Application

## Self-Assembled Pillar-like Structures in Nanodiamond Layers by Pulsed Spray Technique

Pillar-like structures of nanodiamonds on a silicon substrate are self-assembled for the first time by a pulsed spray technique.



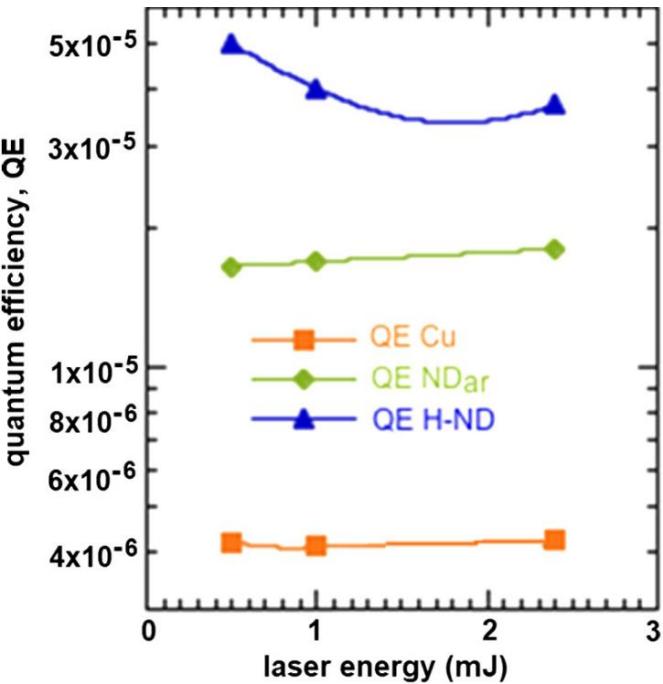
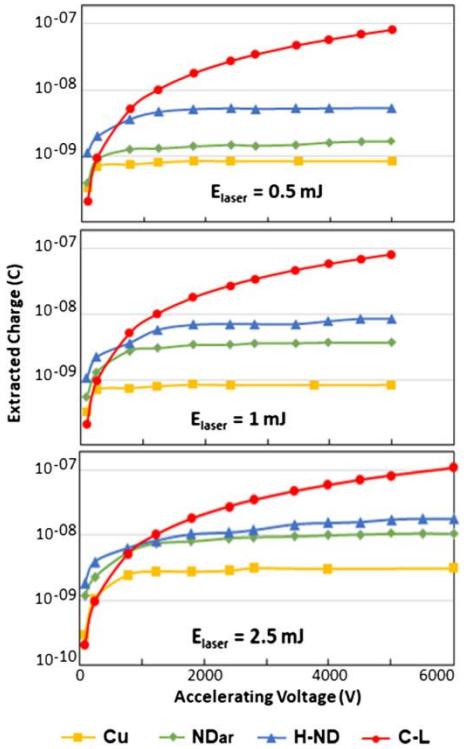
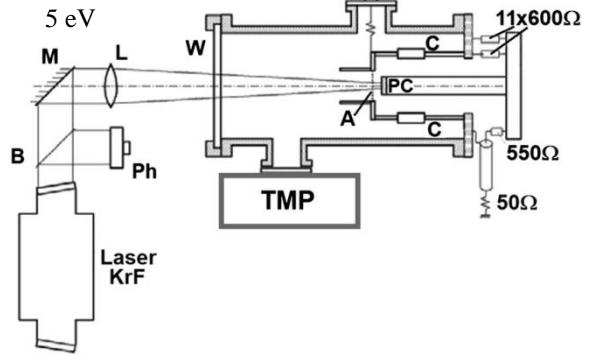
Suggested layout of a biochip on  
(a) glass and  
(b) silicon substrates,  
based on arrays of sprayed  
ND spots obtained by a mask





# Nanodiamond Application

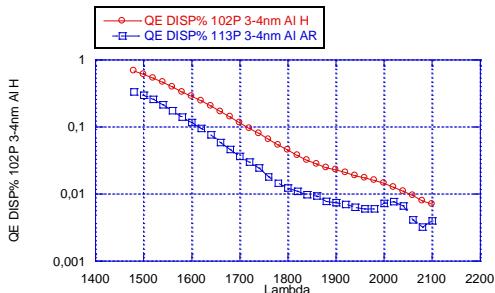
## Electron Beams Produced by Innovative Photocathodes Based on Nanodiamond Layers



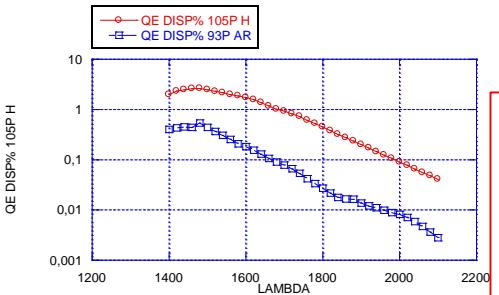
Photoemitted extracted charge of the Cu, NDar and H-ND-based cathodes and the Child-Langmuir (C-L) red curve as function of the accelerating voltage.

# QE Nanodiamond

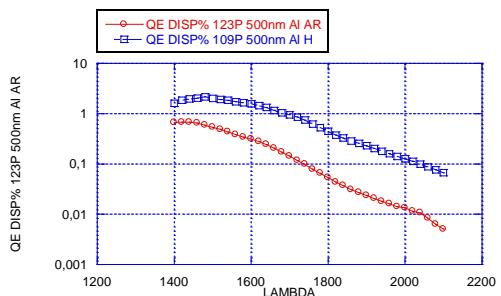
## New Powders



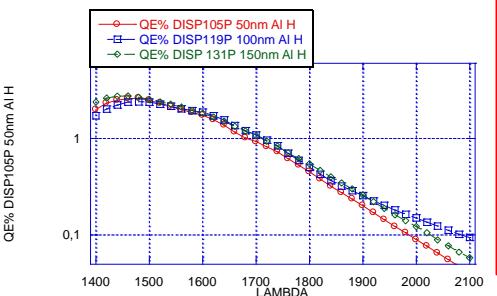
ND-B Doped 95% - 3-4nm



Vammoppes 50nm



ND-Diamonds & Tools – 500 nm



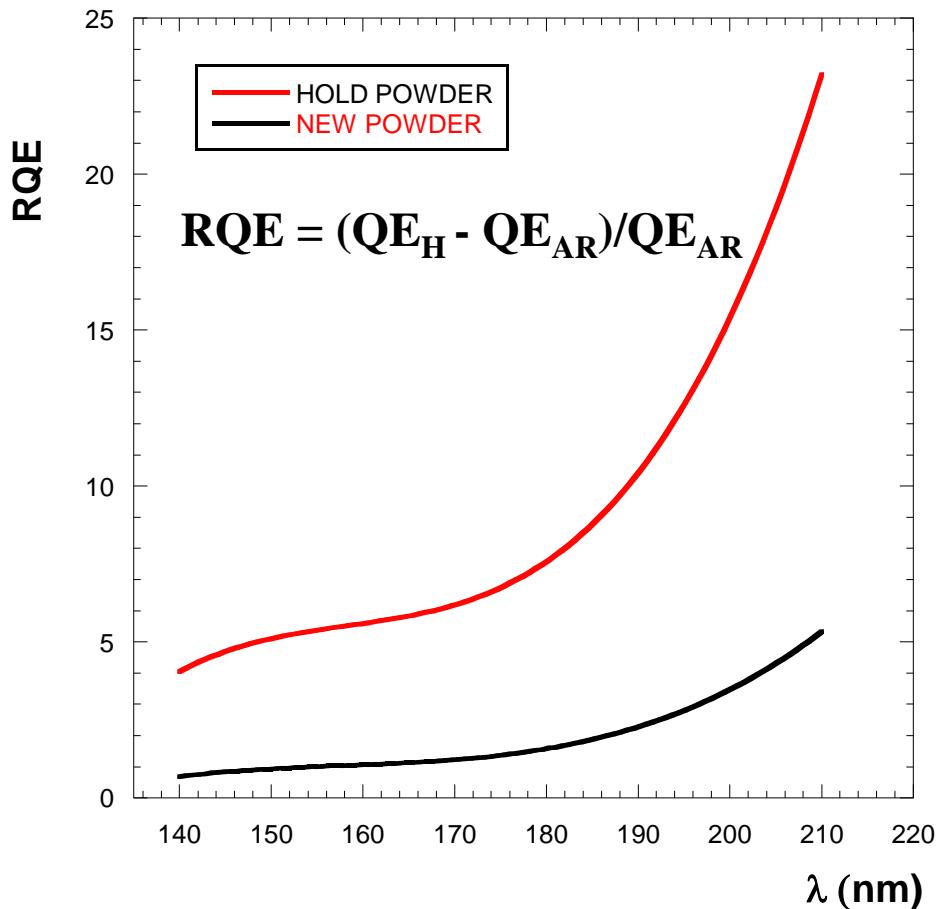
Vammoppes H  
50nm 100 nm 150 nm

➤ Very small grains give low QE:  
 - Only a single grain  
 partecipates to photoemission!

➤ Grain size greater than 50 nm  
 does not change QE:  
 - The mean free path of  
 electrons is about 50 nm!

➤ .....

## *New Powders \**

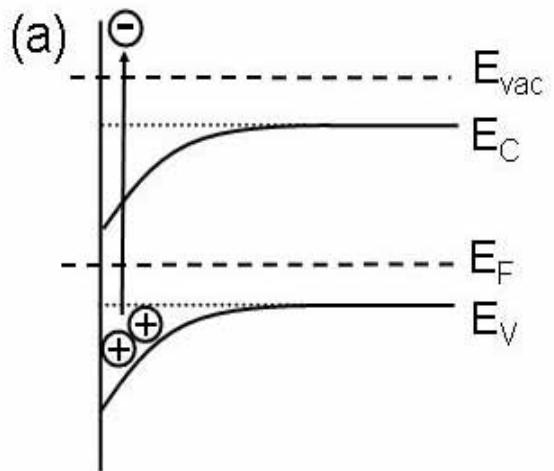


- QE dependence on the properties of the individual grains:
  - Surface chemical properties are very important

\* Same powder !??? From same supplier

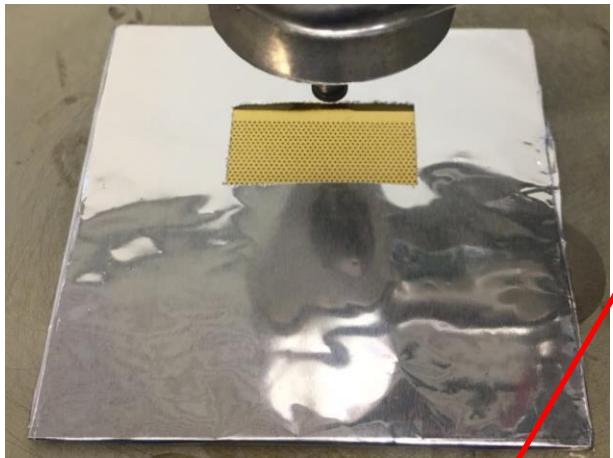
The research on diamond powders continues with particular attention to:

- ✓ Powder reproducible chemical and morphological properties
- ✓ Boron doped diamond (p-type) powders



- ✓ *Applications in MicroPattern Gaseous Detectors*

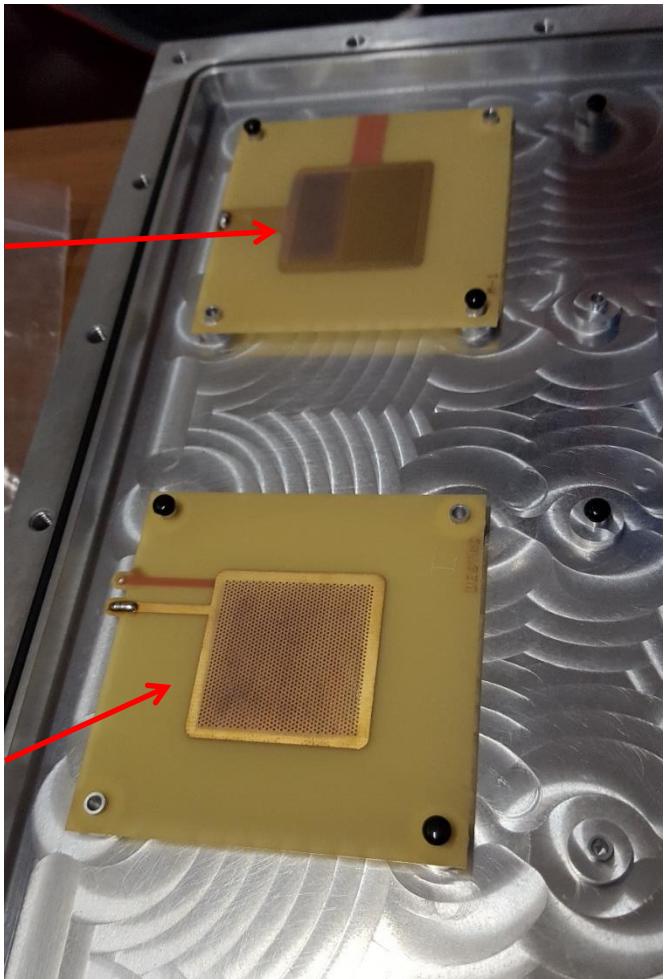
# Nanodiamond PCs on MPGD



Half  
Covered  
THGEM

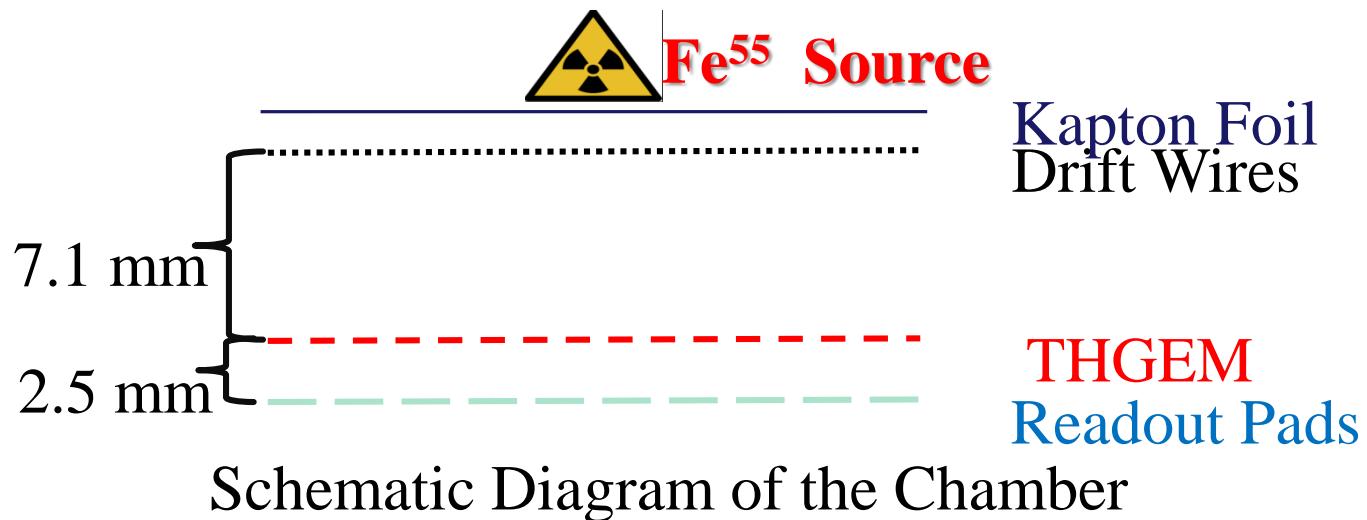


Full  
Covered  
THGEM





## Test - Trieste Group



Half coated with  
non-Hydrogenated  
ND



# Nanodiamond PCs on MPGD

## First Test Results

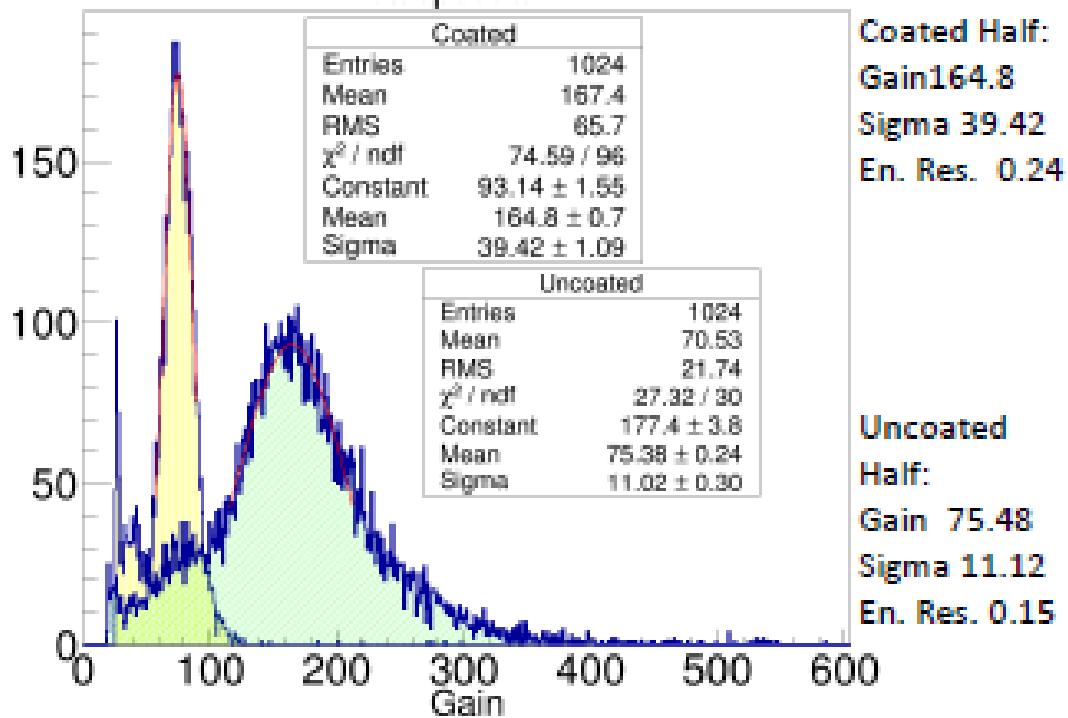


Figure 4: Gain behavior of THGEM with 20  $\mu\text{m}$  rim, half-coated with nanodiamond. It is clearly shown that the gain in the coated part is almost two times higher than that in the uncoated part.

# Preliminary results of ND Photocathode coupled to THGEMs

S. Dasgupta and Triloki

On Behalf of a INFN, Trieste &  
INFN, Bari collaboration

10/02/2020

## Outline

- Motivation
- QE Setup in Bari
- QE measurement in Bari
- ASSET @ CERN
- Preliminary measurement with ASSET
- Conclusion

Triloki (On behalf of INFN Trieste &  
INFN Bari collaboration)

# Thanks for the attention

500 nm